**Data Sheet** 

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# Low-Cost 16-bit DSP with DDR Controller and 10/100 Mbps Ethernet MAC

# MAP-BGA-400 17 mm × 17 mm

**MSC7116** 

- StarCore<sup>®</sup> SC1400 DSP extended core with one SC1400 DSP core, 192 Kbyte of internal SRAM M1 memory, 16 way 16 Kbyte instruction cache (ICache), four-entry write buffer, programmable interrupt controller (PIC), and low-power Wait and Stop processing modes.
- 192 Kbyte M2 memory for critical data and temporary data buffering.
- 8 Kbyte boot ROM.
- AHB-Lite crossbar switch that allows parallel data transfers
  between four master ports and six slave ports, where each port
  connects to an AHB-Lite bus; fixed or round robin priority
  programmable at each slave port; programmable bus parking at
  each slave port; low power mode.
- Internal PLL generates up to 266 MHz clock for the SC1400 core and up to 133 MHz for the crossbar switch, DMA channels, M2 memory, and other peripherals.
- Clock synthesis module provides predivision of PLL input clock; independent clocking of the internal timers and DDR module; programmable operation in the SC1400 low power Stop mode; independent shutdown of different regions of the device.
- Enhanced 16-bit wide host interface (HDI16) provides a glueless connection to industry-standard microcomputers, microprocessors, and DSPs and can also operate with an 8-bit host data bus, making if fully compatible with the DSP56300 HI08 from the external host side.
- DDR memory controller that supports byte enables for up to a 32-bit data bus; glueless interface to 133 MHz 14-bit page mode DDR-RAM; 14-bit external address bus supporting up to 1 Gbyte; and 16-bit or 32-bit external data bus.
- Programmable memory interface with independent read buffers, programmable predictive read feature for each buffer, and a write buffer.
- System control unit performs software watchdog timer function; includes programmable bus time-out monitors on AHB-Lite slave buses; includes bus error detection and programmable time-out monitors on AHB-Lite master buses; and has address out-of-range detection on each crossbar switch buses.
- Event port collects and counts important signal events including DMA and interrupt requests and trigger events such as interrupts, breakpoints, DMA transfers, or wake-up events; units operate independently, in sequence, or triggered externally; can be used standalone or with the OCE10.

- Multi-channel DMA controller with 32 time-multiplexed unidirectional channels, priority-based time-multiplexing between channels using 32 internal priority levels, fixed- or round-robin-priority operation, major-minor loop structure, and DONE or DRACK protocol from requesting units.
- Two independent TDM modules with independent receive and transmit, programmable sharing of frame sync and clock, programmable word size (8 or 16-bit), hardware-base A-law/μ-law conversion, up to 50 Mbps data rate per TDM, up to 128 channels, with glueless interface to E1/T1 frames and MVIP, SCAS, and H.110 buses.
- Ethernet controller with support for 10/100 Mbps MII/RMII designed to comply with IEEE Std. 802.3<sup>TM</sup>, 802.3u<sup>TM</sup>, 802.3u<sup>TM</sup>, and 802.3ac<sup>TM</sup>; with internal receive and transmit FIFOs and a FIFO controller; direct access to internal memories via its own DMA controller; full and half duplex operation; programmable maximum frame length; virtual local area network (VLAN) tag and priority support; retransmission of transmit FIFO following collision; CRC generation and verification for inbound and outbound packets; and address recognition including promiscuous, broadcast, individual address. hash/exact match, and multicast hash match.
- UART with full-duplex operation up to 5.0 Mbps.
- Up to 41 general-purpose input/output (GPIO) ports.
- I<sup>2</sup>C interface that allows booting from EEPROM devices up to 1 Mbyte.
- Two quad timer modules, each with sixteen configurable 16-bit timers
- fieldBIST<sup>TM</sup> unit detects and provides visibility into unlikely field
  failures for systems with high availability to ensure structural
  integrity, that the device operates at the rated speed, is free from
  reliability defects, and reports diagnostics for partial or complete
  device inoperability.
- Standard JTAG interface allows easy integration to system firmware and internal on-chip emulation (OCE10) module.
- Optional booting external host via 8-bit or 16-bit access through the HDI16, 1<sup>2</sup>C, or SPI using in the boot ROM to access serial SPI Flash/EEPROM devices; different clocking options during boot with the PLL on or off using a variety of input frequency ranges.



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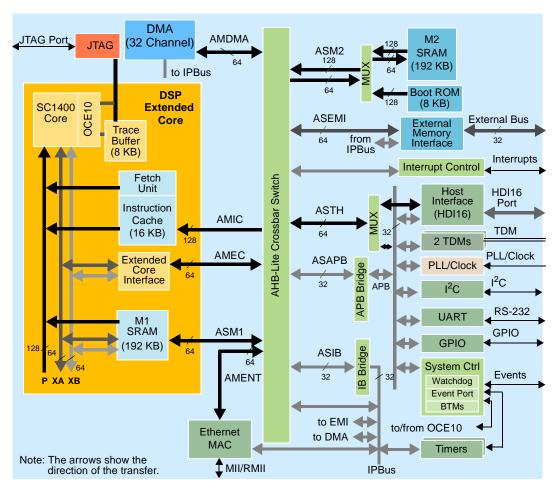


Figure 1. MSC7116 Block Diagram

# 1 Pin Assignments

This section includes diagrams of the MSC7116 package ball grid array layouts and pinout allocation tables.

# 1.1 MAP-BGA Ball Layout Diagrams

Top and bottom views of the MAP-BGA package are shown in Figure 2 and Figure 3 with their ball location index numbers.

Top View 1 2 3 5 6 8 10 12 13 14 15 16 17 18 19 20 4 11 DQM1 GND DQS2 CK HD15 HD12 HD10 HD4 GND HD7 HD6 HD1 HD0 GND вмз NC NC CS0 DQM2 DQS3 DQS0 WE HD14 HD11 NC В  $V_{DDM}$ DQS1 D30 D25 CS1 DQM3 DQM0 RAS CAS HD13 HD9 HD3 NC NC NC С GND D28 D27  $V_{DDM}$  $V_{DDM}$  $V_{DDM}$  $V_{DDM}$ NC  $V_{DDM}$  $V_{DDM}$  $V_{DDIO}$ V<sub>DDIC</sub> V<sub>DDIO</sub>  $V_{DDIO}$  $V_{DDIO}$ V<sub>DDIC</sub> D Е  $V_{DDM}$  $V_{DDM}$  $V_{DDC}$  $V_{DDC}$  $V_{DDC}$  $V_{DDC}$  $V_{DDM}$  $V_{DDIO}$ V<sub>DDIC</sub> V<sub>DDIO</sub> V<sub>DDIO</sub> V<sub>DDIO</sub>  $V_{DDC}$  $V_{DDC}$ NC  $V_{\text{DDC}}$ D15 D29  $V_{DDC}$  $V_{DDC}$ GND GND GND GND GND GND  $V_{DDC}$  $V_{DDC}$ NC  $V_{DDM}$  $V_{DDM}$ V<sub>DDIC</sub> F GND GND GND GND GND GND GND GND GND D13 GND NC G GND GND GND GND GND GND GND GND GND D12 D11  $V_{DDM}$ V<sub>DDIO</sub> V<sub>DDIO</sub>  $V_{DDC}$ HA1 Н  $V_{\text{DDM}}$ GND GND GND GND GND GND GND GND HREQ  $V_{DDM}$  $V_{DDM}$  $V_{\text{DDM}}$ V<sub>DDIO</sub>  $V_{DDC}$ HA3 GND HDS  $V_{\mathsf{DDC}}$  $V_{\text{DDM}}$ V<sub>DDIO</sub>  $V_{DDIO}$  $V_{DDC}$ HA0 HDDS Κ GND GND GND GND GND GND GND GND GND HCS2 HCS' HRW  $V_{DDC}$  $V_{DDM}$  $V_{DDIO}$ V<sub>DDIO</sub> V<sub>DDIO</sub>  $V_{DDC}$ GND GND URXD  $V_{DDM}$  $V_{DDM}$  $V_{DDM}$  $V_{DDC}$  $V_{DDC}$ GND GND GND GND GND GND GND GND CLKIN  $V_{REF}$  $V_{\text{DDM}}$  $V_{\text{DDM}}$  $V_{DDM}$ V<sub>DDIO</sub>  $V_{\text{DDC}}$ V<sub>SSPL</sub> Ν ORESE D17 D16  $V_{DDM}$  $V_{DDM}$ GND GND GND GND GND GND GND GND V<sub>DDIO</sub> V<sub>DDIO</sub>  $V_{DDC}$ TPSE V<sub>DDPL</sub> TESTO R  $V_{DDM}$  $V_{DDM}$  $V_{DDM}$  $V_{DDM}$  $V_{DDM}$ V<sub>DDIO</sub>  $V_{DDIO}$ V<sub>DDIO</sub> D20 D22  $V_{\text{DDM}}$  $V_{DDM}$  $V_{DDC}$  $V_{DDM}$  $V_{\text{DDM}}$  $V_{DDC}$  $V_{DDM}$  $V_{DDM}$  $V_{DDIO}$  $V_{DDIO}$  $V_{DDIO}$ V<sub>DDIO</sub>  $V_{DDC}$  $V_{DDC}$ MDIO TMS HRESET TRST D21 D23  $V_{DDC}$ COL TCK U EVNT4 TOTCK T1RFS T1TD TX\_ER EVNT1 EVNT2 TORFS TOTFS T1RD T1TFS TXD2 RXD3 TXD1 TXCLK RX\_EF GND MDC W  $V_{DDM}$ GND EVNT3 T0RCk T0RD TOTD . T1RCk TXD3 RXD1 RXCL GND RX\_D\

Figure 2. MSC7116 Molded Array Process-Ball Grid Array (MAP-BGA), Top View

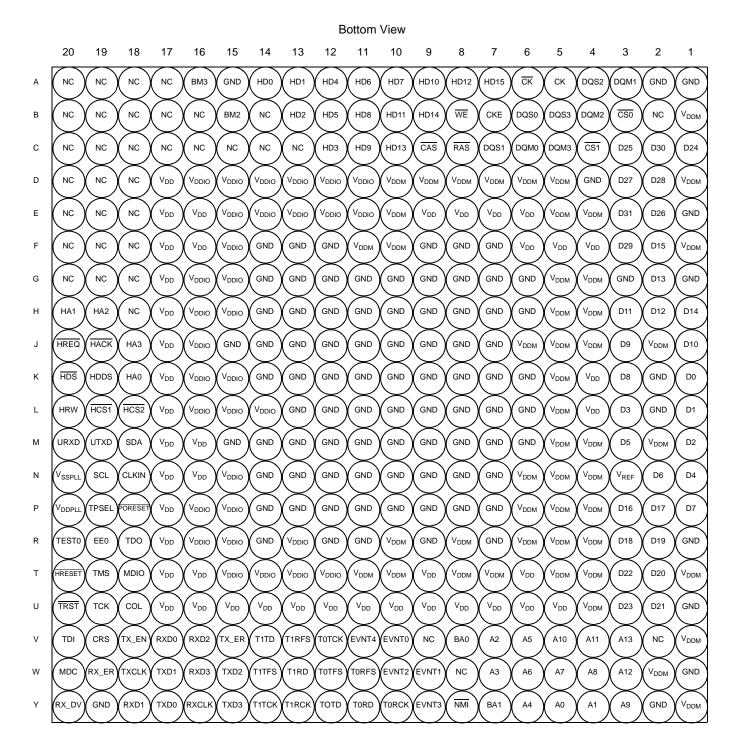


Figure 3. MSC7116 Molded Array Process-Ball Grid Array (MAP-BGA), Bottom View

# 1.2 Signal List By Ball Location

**Table 1** lists the signals sorted by ball number and configuration.

Table 1. MSC7116 Signals by Ball Designator

	Signal Names									
Number		S	oftware Controlle	ed	Hardware	Controlled				
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
A1		GND								
A2		GND								
А3		DQM1								
A4			DC	QS2						
A5			C	CK						
A6			ā	<del>K</del>						
A7		GPIC7		GPOC7	Н	015				
A8		GPIC4		GPOC4	Н	012				
A9		GPIC2 GPOC2				010				
A10		rese	rved		Н	D7				
A11		rese	rved		Н	D6				
A12		rese	rved		Н	HD4				
A13		rese	rved		Н	D1				
A14		rese	rved		Н	D0				
A15			G	ND						
A16	ВМ3	GP	ID8	GPOD8	rese	erved				
A17			N	IC						
A18			N	IC						
A19			١	IC						
A20			N	IC						
B1			V <sub>E</sub>	DDM						
B2			١	IC						
В3			C	S0						
B4			DO	QM2						
B5			DC	QS3						
B6			DC	QS0						
В7			С	KE						
B8			V	VE						
В9		GPIC6		GPOC6	Н	014				
B10		GPIC3		GPOC3	Н	011				
B11		GPIC0		GPOC0	Н	D8				
B12		rese	rved		Н	D5				
B13		rese	rved		Н	D2				

Table 1. MSC7116 Signals by Ball Designator (continued)

	Signal Names									
Number		S	Software Controlled			Hardware Controlled				
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
B14			N	IC						
B15	BM2	GPI	ID7	GPOD7	rese	erved				
B16			N	IC						
B17			N	IC						
B18			N	IC						
B19			N	IC						
B20			N	IC						
C1			D	24						
C2			D	30						
C3			D	25						
C4			C	<u>S1</u>						
C5			DO	QM3						
C6			DO	QMO						
C7			DC	QS1						
C8			R	AS						
C9			C	AS						
C10		GPIC5		GPOC5	Н	D13				
C11		GPIC1		GPOC1	Н	D9				
C12		rese	rved		Н	D3				
C13			N	IC						
C14			N	IC						
C15			N	IC						
C16			N	IC						
C17			N	IC						
C18			N	IC						
C19			N	IC						
C20			N	IC						
D1			V <sub>E</sub>	DDM						
D2			D	28						
D3			D	27						
D4			G	ND						
D5			V <sub>E</sub>	DDM						
D6			V <sub>E</sub>	DDM						
D7			V <sub>E</sub>	DDM						
D8			V <sub>E</sub>	DDM						
D9			V <sub>E</sub>	DDM						

Table 1. MSC7116 Signals by Ball Designator (continued)

	Signal Names									
Number		So	Software Controlled			Hardware Controlled				
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
D10			V <sub>I</sub>	DDM						
D11			V <sub>[</sub>	DDIO						
D12		$V_{DDIO}$								
D13		V <sub>DDIO</sub>								
D14			V	DDIO						
D15			V <sub>[</sub>	DDIO						
D16			V <sub>[</sub>	DDIO						
D17			VI	DDC						
D18				NC .						
D19			١	IC .						
D20			1	IC						
E1			G	ND						
E2			С	26						
E3			С	931						
E4			V <sub>I</sub>	DDM						
E5				DDM						
E6				DDC						
E7				DDC						
E8				DDC						
E9				DDC						
E10				DDM						
E11				DDIO						
E12				DDIO						
E13				DDIO						
E14				DDIO						
E15				DDIO						
E16				DDC						
E17				DDC						
E18				IC						
E19			1	IC						
E20			1	IC						
F1			V <sub>I</sub>	DDM						
F2				115						
F3				29						
F4			V <sub>I</sub>	DDC						
F5				DDC						

Table 1. MSC7116 Signals by Ball Designator (continued)

	Signal Names									
Number		Software Controlled			Hardware Controlled					
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
F6		V <sub>DDC</sub>								
F7		GND								
F8		GND								
F9			G	ND						
F10			V <sub>C</sub>	DDM						
F11			V <sub>C</sub>	DDM						
F12			G	ND						
F13			G	ND						
F14			G	ND						
F15			V <sub>D</sub>	DDIO						
F16				DDC						
F17				DDC						
F18				IC						
F19			Ν	IC						
F20			Ν	IC						
G1			G	ND						
G2			D	13						
G3			G	ND						
G4			V <sub>D</sub>	DDM						
G5				DDM						
G6				ND						
G7			G	ND						
G8			G	ND						
G9			G	ND						
G10			G	ND						
G11			G	ND						
G12			G	ND						
G13			G	ND						
G14			G	ND						
G15			V <sub>D</sub>	DDIO						
G16				DDIO						
G17				DDC						
G18				IC						
G19			N	IC						
G20			N	IC						
H1				14						

Table 1. MSC7116 Signals by Ball Designator (continued)

	Signal Names									
Number		S	Software Controlled			Hardware Controlled				
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
H2			D	12						
НЗ		D11								
H4		$V_{DDM}$								
H5		V <sub>DDM</sub>								
H6			GI	ND						
H7			GI	ND						
H8			GI	ND						
H9			GI	ND						
H10			GI	ND						
H11			GI	ND						
H12			GI	ND						
H13			GI	ND						
H14			GI	ND						
H15			V <sub>D</sub>	DIO						
H16				DIO						
H17				DDC						
H18				С						
H19		rese	rved		Н	IA2				
H20		rese	rved		Н	IA1				
J1			D	10						
J2			V <sub>D</sub>	DM						
J3				9						
J4			V <sub>D</sub>	DM						
J5				DM						
J6				DM						
J7				ND						
J8			GI	ND						
J9			GI	ND						
J10			GI	ND						
J11			GI	ND						
J12			GI	ND						
J13			GI	ND						
J14				ND						
J15				ND						
J16			V <sub>D</sub>	DIO						
J17				DDC						

Table 1. MSC7116 Signals by Ball Designator (continued)

	Signal Names									
Number		S	oftware Controll	ed	Hardware	Controlled				
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
J18		GPIC11		GPOC11	Н	A3				
J19		rese	rved		HACK/HACK or HRRQ/HRRQ					
J20	HDSP		reserved		HREQ/HREQ	or HTRQ/HTRQ				
K1				D0						
K2			G	iND						
K3				D8						
K4			V	DDC						
K5			V	DDM						
K6			0	IND						
K7				IND						
K8				iND						
K9			0	IND						
K10			G	IND						
K11			G	iND						
K12			G	IND						
K13			G	IND						
K14			G	IND						
K15			V	ODIO						
K16			V	ODIO						
K17			V	DDC						
K18		rese	rved		Н	A0				
K19		rese	rved		Н	DDS				
K20		rese	rved		HDS/HDS o	or HWR/HWR				
L1				D1						
L2			0	IND						
L3				D3						
L4			V	DDC						
L5			V	DDM						
L6			G	IND						
L7			G	ND						
L8			G	ND						
L9			G	ND						
L10			G	ND						
L11			G	ND						
L12			G	ND						
L13			G	IND						

Table 1. MSC7116 Signals by Ball Designator (continued)

	Signal Names									
Number		S	oftware Controll	ed	Hardware	Controlled				
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
L14			V	ODIO		•				
L15			V	ODIO						
L16		$V_{DDIO}$								
L17		V <sub>DDC</sub>								
L18		GPIB11	GPOB11	HCS2	P/HCS2					
L19		rese	rved		HCS1	/HCS1				
L20		rese	rved		HRW or	HRD/HRD				
M1				D2						
M2			V	DDM						
M3				D5						
M4			V	DDM						
M5			V	DDM						
M6			G	ND						
M7			G	ND						
M8			G	ND						
M9			G	ND						
M10			G	ND						
M11			G	ND						
M12			G	ND						
M13			G	ND						
M14			G	ND						
M15			G	ND						
M16			V	DDC						
M17				DDC						
M18	GPI	A14	ĪRQ15	GPOA14	S	DA				
M19	GPI	A12	ĪRQ3	GPOA12	U	ΓXD				
M20	GPI	A13	ĪRQ2	GPOA13	UF	RXD				
N1				D4						
N2				D6						
N3			V	REF						
N4				DDM						
N5				DDM						
N6				DDM						
N7				ND						
N8			G	ND						
N9			G	ND						

Table 1. MSC7116 Signals by Ball Designator (continued)

	Signal Names										
Number		s	Software Controlled			Hardware Controlled					
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate					
N10		GND									
N11		GND									
N12			GI	ND							
N13			GI	ND							
N14			GI	ND							
N15			V <sub>D</sub>	DIO							
N16			V <sub>C</sub>	DC							
N17			V <sub>E</sub>	DC							
N18			CL	KIN							
N19	GPI	A15	ĪRQ14	GPOA15	S	CL					
N20			V <sub>SS</sub>	SPLL							
P1				7							
P2			D	17							
P3			D	16							
P4			V <sub>D</sub>	DM							
P5				DM							
P6			V <sub>D</sub>	DM							
P7				ND							
P8			GI	ND							
P9			GI	ND							
P10			GI	ND							
P11			GI	ND							
P12			GI	ND							
P13			GI	ND							
P14			GI	ND							
P15			V <sub>D</sub>	DIO							
P16				DIO							
P17				DC							
P18				ESET							
P19			TP	SEL							
P20			V <sub>DI</sub>	PLL							
R1				ND							
R2			D	19							
R3			D	18							
R4			V <sub>D</sub>	DM							
R5				DM							

Table 1. MSC7116 Signals by Ball Designator (continued)

	Signal Names									
Number		s	Software Controlled			Controlled				
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
R6			V <sub>E</sub>	DDM						
R7			G	ND						
R8		$V_{DDM}$								
R9		GND								
R10			V <sub>E</sub>	DDM						
R11			G	ND						
R12			G	ND						
R13			V <sub>C</sub>	DDIO						
R14			G	ND						
R15			V <sub>C</sub>	DDIO						
R16			V <sub>C</sub>	DDIO						
R17				DDC						
R18	TDO									
R19		rese	rved		EE0/[	DBREQ				
R20			TE	ST0						
T1			V <sub>E</sub>	DDM						
T2			D	20						
Т3			D	22						
T4			V <sub>E</sub>	DDM						
T5			V <sub>E</sub>	DDM						
T6			V <sub>L</sub>	DDC						
T7				DDM						
T8				DDM						
Т9				DDC						
T10				DDM						
T11				DDM						
T12				DDIO						
T13				DDIO						
T14				DDIO						
T15				DDIO						
T16				DDC						
T17				DDC						
T18		rese			М	DIO				
T19			TI	MS						
T20			HRE	ESET						
U1			G	ND						

Table 1. MSC7116 Signals by Ball Designator (continued)

	Signal Names									
Number		Software Controlled				Controlled				
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
U2			С	021						
U3			C	)23						
U4			V <sub>I</sub>	DDM						
U5			V	DDC						
U6			V	DDC						
U7			V	DDC						
U8			VI	DDC						
U9			VI	DDC						
U10			V	DDC						
U11			VI	DDC						
U12			VI	DDC						
U13			V <sub>I</sub>	DDC						
U14			VI	DDC						
U15			VI	DDC						
U16			V <sub>I</sub>	DDC						
U17			VI	DDC						
U18		rese	rved		CC	DL				
U19			Т	СК						
U20			TF	RST						
V1			V <sub>I</sub>	DDM						
V2				NC .						
V3			Α	13						
V4			Α	<b>\11</b>						
V5			Α	10						
V6			,	<b>4</b> 5						
V7			,	<b>A</b> 2						
V8			В	A0						
V9			1	NC						
V10		rese	rved		EVN	NT0				
V11	SWTE	GPIA16	ĪRQ12	GPOA16	EVN	NT4				
V12	GP	IA8	ĪRQ6	GPOA8	ТОТ	CK				
V13	GP	IA4	ĪRQ1	GPOA4	T1R	RFS				
V14	GP	IA0	ĪRQ11	GPOA0	T1	TD				
V15	GPI	GPIA28 IRQ17 GPOA28 TX_ER reserved								
V16		GPID6	•	GPOD6	RXD2	reserved				
V17	GPI	A22	IRQ22	GPOA22	RX	D0				

Table 1. MSC7116 Signals by Ball Designator (continued)

	Signal Names									
Number		S	oftware Control	led	Hardware	Controlled				
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate				
V18	GPI	A24	ĪRQ24	GPOA24	TX_	_EN				
V19		rese	rved		CF	RS				
V20				TDI						
W1			(	SND						
W2			V	DDM						
W3				<b>A12</b>						
W4				A8						
W5				A7						
W6				A6						
W7				A3						
W8				NC						
W9	GPI	A17	ĪRQ13	GPOA17	EVNT1	CLKO				
W10	BM0	GPI	C14	GPOC14	EVI	NT2				
W11	GPI	A10	ĪRQ5	GPOA10	T0RFS					
W12	GP	IA7	ĪRQ7	GPOA7	ТОТ	TFS				
W13	GP	IA3	ĪRQ8	GPOA3	T1RD					
W14	GP	IA1	ĪRQ10	GPOA1	T17	TFS				
W15		GPID4		GPOD4	TXD2	reserved				
W16	GPI	A27	ĪRQ18	GPOA27	RXD3	reserved				
W17	GPI	A19	ĪRQ19	GPOA19	TX	D1				
W18	GPI	A23	ĪRQ23	GPOA23	TXCLK or REFCLK					
W19	GPI	A26	ĪRQ26	GPOA26	RX_ER					
W20	H8BIT		reserved		MDC					
Y1			V	DDM						
Y2			(	GND						
Y3				A9						
Y4				A1						
Y5				A0						
Y6				A4						
Y7			·	BA1						
Y8	rese	rved	NMI		reserved					
Y9	BM1	GPI	C15	GPOC15	C15 EVNT3					
Y10	GPI	A11	ĪRQ4	GPOA11	TORCK					
Y11		GPIA9		GPOA9	TORD					
Y12		GPIA6		GPOA6	TOTD					
Y13	GP	IA5	ĪRQ0	GPOA5	T1R	RCK				

Table 1. MSC7116 Signals by Ball Designator (continued)

	Signal Names					
Number		Software Controlled			Hardware Controlled	
	End of Reset	GPI Enabled (Default)	Interrupt Enabled	GPO Enabled	Primary	Alternate
Y14	GPIA2		ĪRQ9	GPOA2	T1TCK	
Y15	GPI	A29	ĪRQ16	GPOA29	TXD3	reserved
Y16		GPID5		GPOD5	RXCLK	reserved
Y17	GPI	A20	ĪRQ20	GPOA20	TX	(D0
Y18	GPIA21		ĪRQ21	GPOA21	RX	(D1
Y19	GND					
Y20	GPIA25		ĪRQ25	GPOA25	RX_DV o	r CRS_DV

## 2 Electrical Characteristics

This document contains detailed information on power considerations, DC/AC electrical characteristics, and AC timing specifications. For additional information, see the MSC711x Reference Manual.

# 2.1 Maximum Ratings

#### **CAUTION**

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, normal precautions should be taken to avoid exceeding maximum voltage ratings. Reliability is enhanced if unused inputs are tied to an appropriate logic voltage level (for example, either GND or  $V_{DD}$ ).

In calculating timing requirements, adding a maximum value of one specification to a minimum value of another specification does not yield a reasonable sum. A maximum specification is calculated using a worst case variation of process parameter values in one direction. The minimum specification is calculated using the worst case for the same parameters in the opposite direction. Therefore, a "maximum" value for a specification never occurs in the same device with a "minimum" value for another specification; adding a maximum to a minimum represents a condition that can never exist.

#### **Electrical Characteristics**

**Table 2** describes the maximum electrical ratings for the MSC7116.

**Table 2. Absolute Maximum Ratings** 

Rating	Symbol	Value	Unit
Core supply voltage	V <sub>DDC</sub>	1.5	V
Memory supply voltage	$V_{DDM}$	4.0	V
PLL supply voltage	V <sub>DDPLL</sub>	1.5	V
I/O supply voltage	V <sub>DDIO</sub>	-0.2 to 4.0	V
Input voltage	V <sub>IN</sub>	(GND – 0.2) to 4.0	V
Reference voltage	V <sub>REF</sub>	4.0	V
Maximum operating temperature	TJ	105	°C
Minimum operating temperature	T <sub>A</sub>	-40	°C
Storage temperature range	T <sub>STG</sub>	-55 to +150	°C

Notes:

- 1. Functional operating conditions are given in Table 3.
- 2. Absolute maximum ratings are stress ratings only, and functional operation at the maximum is not guaranteed. Stress beyond the listed limits may affect device reliability or cause permanent damage.
- 3. Section 3.1, Thermal Design Considerations includes a formula for computing the chip junction temperature (T<sub>J</sub>).

# 2.2 Recommended Operating Conditions

Table 3 lists recommended operating conditions. Proper device operation outside of these conditions is not guaranteed.

**Table 3. Recommended Operating Conditions** 

Rating	Symbol	Value	Unit
Core supply voltage	V <sub>DDC</sub>	1.14 to 1.26	V
Memory supply voltage	V <sub>DDM</sub>	2.38 to 2.63	V
PLL supply voltage	V <sub>DDPLL</sub>	1.14 to 1.26	V
I/O supply voltage	V <sub>DDIO</sub>	3.14 to 3.47	V
Reference voltage	V <sub>REF</sub>	1.19 to 1.31	V
Operating temperature range	T <sub>J</sub> T <sub>A</sub>	maximum: 105 minimum: –40	°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°°

## 2.3 Thermal Characteristics

**Table 4** describes thermal characteristics of the MSC7116 for the MAP-BGA package.

**Table 4. Thermal Characteristics for MAP-BGA Package** 

		MAP-BGA			
Characteristic	Symbol	Natural Convection	200 ft/min (1 m/s) airflow	Unit	
Junction-to-ambient <sup>1, 2</sup>	$R_{\theta JA}$	39	31	°C/W	
Junction-to-ambient, four-layer board <sup>1, 3</sup>	$R_{ heta JA}$	23	20	°C/W	
Junction-to-board <sup>4</sup>	$R_{ heta JB}$	12		°C/W	
Junction-to-case <sup>5</sup>	$R_{ heta JC}$	7		°C/W	
Junction-to-package-top <sup>6</sup>	$\Psi_{JT}$	2		°C/W	

Notes:

- Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
- 2. Per SEMI G38-87 and JEDEC JESD51-2 with the single layer board horizontal.
- 3. Per JEDEC JESD51-6 with the board horizontal.
- 4. Thermal resistance between the die and the printed circuit board per JEDEC JESD 51-8. Board temperature is measured on the top surface of the board near the package.
- 5. Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).
- **6.** Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2.

Section 3.1, Thermal Design Considerations explains these characteristics in detail.

## 2.4 DC Electrical Characteristics

This section describes the DC electrical characteristics for the MSC7116.

**Note:** The leakage current is measured for nominal voltage values must vary in the same direction (for example, both  $V_{DDIO}$  and  $V_{DDC}$  vary by +2 percent or both vary by -2 percent).

**Table 5. DC Electrical Characteristics** 

Characteristic	Symbol	Min	Typical	Max	Unit
Core and PLL voltage	V <sub>DDC</sub> V <sub>DDPLL</sub>	1.14	1.2	1.26	V
DRAM interface I/O voltage <sup>1</sup>	$V_{DDM}$	2.375	2.5	2.625	V
I/O voltage	V <sub>DDIO</sub>	3.135	3.3	3.465	V
DRAM interface I/O reference voltage <sup>2</sup>	$V_{REF}$	$0.49 \times V_{DDM}$	1.25	$0.51 \times V_{DDM}$	V
DRAM interface I/O termination voltage <sup>3</sup>	VTT	V <sub>REF</sub> – 0.04	$V_{REF}$	V <sub>REF</sub> + 0.04	V
Input high CLKIN voltage	V <sub>IHCLK</sub>	2.4	3.0	3.465	V
DRAM interface input high I/O voltage	V <sub>IHM</sub>	V <sub>REF</sub> + 0.28	$V_{\rm DDM}$	V <sub>DDM</sub> + 0.3	V
DRAM interface input low I/O voltage	V <sub>ILM</sub>	-0.3	GND	V <sub>REF</sub> – 0.18	V
Input leakage current, V <sub>IN</sub> = V <sub>DDIO</sub>	I <sub>IN</sub>	-1.0	0.09	1	μΑ
V <sub>REF</sub> input leakage current	I <sub>VREF</sub>	_	_	5	μΑ

#### **Electrical Characteristics**

Table 5. DC Electrical Characteristics (continued)

Characteristic	Symbol	Min	Typical	Max	Unit
Tri-state (high impedance off state) leakage current, $V_{IN} = V_{DDIO}$	I <sub>OZ</sub>	-1.0	0.09	1	μA
Signal low input current, V <sub>IL</sub> = 0.4 V	Ι <sub>L</sub>	-1.0	0.09	1	μA
Signal high input current, V <sub>IH</sub> = 2.0 V	I <sub>H</sub>	-1.0	0.09	1	μA
Output high voltage, $I_{OH} = -2$ mA, except open drain pins	V <sub>OH</sub>	2.0	3.0	_	V
Output low voltage, I <sub>OL</sub> = 5 mA	V <sub>OL</sub>	_	0	0.4	V
Typical power at 266 MHz <sup>5</sup>	Р	_	293.0	_	mW

Notes:

- The value of V<sub>DDM</sub> at the MSC7116 device must remain within 50 mV of V<sub>DDM</sub> at the DRAM device at all times.
- V<sub>REF</sub> must be equal to 50% of V<sub>DDM</sub> and track V<sub>DDM</sub> variations as measured at the receiver. Peak-to-peak noise must not exceed ±2% of the DC value.
- V<sub>TT</sub> is not applied directly to the MSC7116 device. It is the level measured at the far end signal termination. It should be equal
  to V<sub>REF</sub>. This rail should track variations in the DC level of V<sub>REF</sub>.
- 4. Output leakage for the memory interface is measured with all outputs disabled,  $0 \text{ V} \leq \text{V}_{\text{OUT}} \leq \text{V}_{\text{DDM}}$ .
- 5. The core power values were measured.using a standard EFR pattern at typical conditions (25°C, 300 MHz, 1.2 V core).

#### Table 6 lists the DDR DRAM capacitance.

#### **Table 6. DDR DRAM Capacitance**

Parameter/Condition	Symbol	Max	Unit
Input/output capacitance: DQ, DQS	C <sub>IO</sub>	30	pF
Delta input/output capacitance: DQ, DQS	C <sub>DIO</sub>	30	pF

Note:

These values were measured under the following conditions:

- $V_{DDM} = 2.5 V \pm 0.125 V$
- f = 1 MHz
- T<sub>A</sub> = 25°C
- $V_{OUT} = V_{DDM}/2$
- V<sub>OUT</sub> (peak to peak) = 0.2 V

# 2.5 AC Timings

This section presents timing diagrams and specifications for individual signals and parallel I/O outputs and inputs. All AC timings are based on a 30 pF load, except where noted otherwise, and a 50  $\Omega$  transmission line. For any additional pF, use the following equations to compute the delay:

Standard interface: 2.45 + (0.054 × C<sub>load</sub>) ns
 DDR interface: 1.6 + (0.002 × C<sub>load</sub>) ns

## 2.5.1 Clock and Timing Signals

The following tables describe clock signal characteristics. **Table 6** shows the maximum frequency values for internal (core, reference, and peripherals) and external (CLKO) clocks. You must ensure that maximum frequency values are not exceeded (see **Section 2.5.2** for the allowable ranges when using the PLL).

**Table 6. Maximum Frequencies** 

Characteristic	Maximum in MHz
Core clock frequency (CLOCK)	266
External output clock frequency (CLKO)	67
Memory clock frequency (CK, CK)	133
TDM clock frequency (TxRCK, TxTCK)	50

Table 7. Clock Frequencies in MHz

Characteristic	Symbol	Min	Max
CLKIN frequency	F <sub>CLKIN</sub>	10	100
CLOCK frequency	F <sub>CORE</sub>	_	266
CK, CK frequency	F <sub>CK</sub>	_	133
TDMxRCK, TDMxTCK frequency	F <sub>TDMCK</sub>	_	50
CLKO frequency	F <sub>CKO</sub>	_	67
AHB/IPBus/APB clock frequency	F <sub>BCK</sub>	_	133
Note: The rise and fall time of external clocks should be 5 ns maximum			

**Table 8. System Clock Parameters** 

Characteristic	Min	Max	Unit
CLKIN frequency	10	100	MHz
CLKIN slope	_	5	ns
CLKIN frequency jitter (peak-to-peak)	_	1000	ps
CLKO frequency jitter (peak-to-peak)	_	133	ps

#### 2.5.2 Configuring Clock Frequencies

This section describes important requirements for configuring clock frequencies in the MSC7116 device when using the PLL block. To configure the device clocking, you must program four fields in the Clock Control Register (CLKCTL):

- *PLLDVF field*. Specifies the PLL division factor (PLLDVF + 1) to divide the input clock frequency F<sub>CLKIN</sub>. The output of the divider block is the input to the multiplier block.
- *PLLMLTF field.* Specifies the PLL multiplication factor (PLLMLTF + 1). The output from the multiplier block is the loop frequency F<sub>LOOP</sub>.
- RNG field. Selects the available PLL frequency range for F<sub>VCO</sub>, either F<sub>LOOP</sub> when the RNG bit is set (1) or F<sub>LOOP</sub>/2 when the RNG bit is cleared (0).
- CKSEL field. Selects  $F_{CLKIN}$ ,  $F_{VCO}$ , or  $F_{VCO}/2$  as the source for the core clock.

There are restrictions on the frequency range permitted at the beginning of the multiplication portion of the PLL that affect the allowable values for the PLLDVF and PLLMLTF fields. The following sections define these restrictions and provide guidelines to configure the device clocking when using the PLL. Refer to the Clock and Power Management chapter in the MSC711x Reference Manual for details on the clock programming model.

#### 2.5.2.1 PLL Multiplier Restrictions

There are two restrictions for correct usage of the PLL block:

- The input frequency to the PLL multiplier block (that is, the output of the divider) must be in the range 10–25 MHz.
- The output frequency of the PLL multiplier must be in the range 266–532 MHz.

When programming the PLL for a desired output frequency using the PLLDVF, PLLMLTF, and RNG fields, you must meet these constraints.

#### 2.5.2.2 Input Division Factors and Corresponding CLKIN Frequency Range

The value of the PLLDVF field determines the allowable CLKIN frequency range, as shown in **Table 9**.

**PLLDVF Input Divide CLKIN Frequency Range** Comments **Field Value Factor** 0x00 1 10 to 25 MHz Input Division by 1 0x01 2 20 to 50 MHz Input Division by 2 30 to 75 MHz Input Division by 3 0x023 0x03 4 40 to 100 MHz Input Division by 4 5 50 to 100 MHz Input Division by 5 0x040x05 6 60 to 100 MHz Input Division by 6 70 to 100 MHz 0x06 7 Input Division by 7 80 to 100 MHz 0x07 8 Input Division by 8 0x08 9 90 to 100 MHz Input Division by 9 0x09 10 100 MHz Input Division by 10 The maximum CLKIN frequency is 100 MHz. Therefore, the PLLDVF value must be in the range from 1-10. Note:

Table 9. CLKIN Frequency Ranges by Divide Factor Value

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### 2.5.2.3 Multiplication Factor Range

The multiplier block output frequency ranges depend on the divided input clock frequency as shown in Table 10.

**Table 10. PLLMLTF Ranges** 

Multiplier Block (Loop) Output Range		Minimum PLLMLTF Value	Maximum PLLMLTF Value	
	266 ≤ [Divided Input Clock × (PLLMLTF + 1)] ≤ 532 MHz	266/Divided Input Clock	532/Divided Input Clock	
Note:	Note: This table results from the allowed range for F <sub>Loop</sub> . The minimum and maximum multiplication factors are dependent on the frequency of the Divided Input Clock.			

#### 2.5.2.4 Allowed Core Clock Frequency Range

The frequency delivered to the core, extended core, and peripherals depends on the value of the CLKCTRL[RNG] bit as shown in **Table 11**.

Table 11. F<sub>vco</sub> Frequency Ranges

CLI	KCTRL[RNG] Value	Allowed Range of F <sub>vco</sub>
	1	266 ≤ F <sub>vco</sub> ≤ 532 MHz
	0	133 ≤ F <sub>vco</sub> ≤ 266 MHz
Note:	This table results from the allowed range for F <sub>vco</sub> , which is F <sub>Loop</sub> modified by CLKCTRL[RNG].	

This bit along with the CKSEL determines the frequency range of the core clock.

**Table 12. Resulting Ranges Permitted for the Core Clock** 

CLKC	TRL[CKSEL]	CLKCTRL[RNG]	Resulting Division Factor	Allowed Range of Core Clock	Comments	
	11 1		1	Reserved	Reserved	
	11	0	2	133 ≤ core clock ≤ 266 MHz	Limited by range of PLL	
	01	1	2	133 ≤ core clock ≤ 266 MHz	Limited by range of PLL	
	01	0	4	66.5 ≤ core clock ≤ 133 MHz	Limited by range of PLL	
Note:	This table results from the allowed range for F <sub>OUT</sub> , which depends on clock selected via CLKCTRL[CKSEL].					

## 2.5.2.5 Core Clock Frequency Range When Using DDR Memory

The core clock can also be limited by the frequency range of the DDR devices in the system. **Table 13** summarizes this restriction.

Table 13. Core Clock Ranges When Using DDR

DDR Type	Allowed Frequency Range for DDR CK	Corresponding Range for the Core Clock	Comments
DDR 200 (PC-1600)	83–100 MHz	166 ≤ core clock ≤ 200 MHz	Core limited to 2 × maximum DDR frequency
DDR 266 (PC-2100) DDR 333 (PC-2600)	83–133 MHz	166 ≤ core clock ≤ 266 MHz	Core limited to 2 × maximum DDR frequency

## 2.5.3 Reset Timing

The MSC7116 device has several inputs to the reset logic. All MSC7116 reset sources are fed into the reset controller, which takes different actions depending on the source of the reset. The reset status register indicates the most recent sources to cause a reset. **Table 14** describes the reset sources.

**Table 14. Reset Sources** 

Name	Direction	Description
Power-on reset (PORESET)	Input	Initiates the power-on reset flow that resets the MSC7116 and configures various attributes of the MSC7116. On PORESET, the entire MSC7116 device is reset. SPLL and DLL states are reset, HRESET is driven, the SC1400 extended core is reset, and system configuration is sampled. The system is configured only when PORESET is asserted.
External Hard reset (HRESET)	Input/ Output	Initiates the hard reset flow that configures various attributes of the MSC7116. While HRESET is asserted, HRESET is an open-drain output. Upon hard reset, HRESET is driven and the SC1400 extended core is reset.
Software watchdog reset	Internal	When the MSC7116 watchdog count reaches zero, a software watchdog reset is signalled. The enabled software watchdog event then generates an internal hard reset sequence.
Bus monitor reset	Internal	When the MSC7116 bus monitor count reaches zero, a bus monitor hard reset is asserted. The enabled bus monitor event then generates an internal hard reset sequence.
JTAG EXTEST, CLAMP, or HIGHZ command	Internal	When a Test Access Port (TAP) executes an EXTEST, CLAMP, or HIGHZ command, the TAP logic asserts an internal reset signal that generates an internal soft reset sequence.

**Table 15** summarizes the reset actions that occur as a result of the different reset sources.

**Table 15. Reset Actions for Each Reset Source** 

	Power-On Reset (PORESET)	H <u>ard Rese</u> t (HRESET)	S <u>oft Rese</u> t (SRESET)
Reset Action/Reset Source	External only	External or Internal (Software Watchdog or Bus Monitor)	JTAG Command: EXTEST, CLAMP, or HIGHZ
Configuration pins sampled (refer to <b>Section 2.5.3.1</b> for details).	Yes	No	No
PLL and clock synthesis states Reset	Yes	No	No
HRESET Driven	Yes	Yes	No
Software watchdog and bus time-out monitor registers	Yes	Yes	Yes
Clock synthesis modules (STOPCTRL, HLTREQ, and HLTACK) reset	Yes	Yes	Yes
Extended core reset	Yes	Yes	Yes
Peripheral modules reset	Yes	Yes	Yes

# 2.5.3.1 Power-On Reset (PORESET) Pin

Asserting  $\overline{\text{PORESET}}$  initiates the power-on reset flow.  $\overline{\text{PORESET}}$  must be asserted externally for at least 16 CLKIN cycles after external power to the MSC7116 reaches at least 2/3  $V_{DD}$ .

## 2.5.3.2 Reset Configuration

The MSC7116 has two mechanisms for writing the reset configuration:

- From a host through the host interface (HDI16)
- From memory through the I<sup>2</sup>C interface

Five signal levels (see **Chapter 1** for signal description details) are sampled on PORESET deassertion to define the boot and operating conditions:

- BM[0-1]
- SWTE
- H8BIT
- HDSP

## 2.5.3.3 Reset Timing Tables

Table 16 and Figure 4 describe the reset timing for a reset configuration write.

Table 16. Timing for a Reset Configuration Write

No.	Characteristics	Expression	Unit
1	Required external PORESET duration minimum	16/F <sub>CLKIN</sub>	clocks
2	Delay from PORESET deassertion to HRESET deassertion	521/F <sub>CLKIN</sub>	clocks
Note:	Timings are not tested, but are guaranteed by design.		

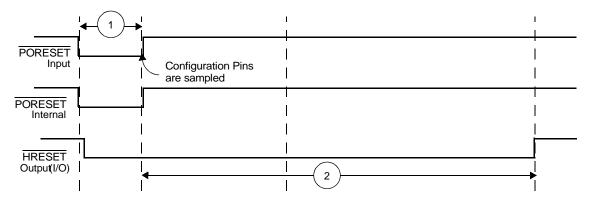


Figure 4. Timing Diagram for a Reset Configuration Write

#### **DDR DRAM Controller Timing** 2.5.4

This section provides the AC electrical characteristics for the DDR DRAM interface.

#### 2.5.4.1 **DDR DRAM Input AC Timing Specifications**

Table 17 provides the input AC timing specifications for the DDR DRAM interface.

Table 17. DDR DRAM Input AC Timing

No.	Parameter	Symbol	Min	Max	Unit
_	AC input low voltage	V <sub>IL</sub>		V <sub>REF</sub> - 0.31	V
_	AC input high voltage	V <sub>IH</sub>	V <sub>REF</sub> + 0.31	V <sub>DDM</sub> + 0.3	V
201	Maximum Dn input setup skew relative to DQSn input	_	_	900	ps
202	Maximum Dn input hold skew relative to DQSn input	_	_	900	ps

Notes:

- Maximum possible skew between a data strobe (DQSn) and any corresponding bit of data (D[8n +  $\{0...7\}$ ] if  $0 \le n \le 7$ ).
- See Table 18 for t<sub>CK</sub> value.
- Dn should be driven at the same time as DQSn. This is necessary because the DQSn centering on the DQn data tenure is done internally.

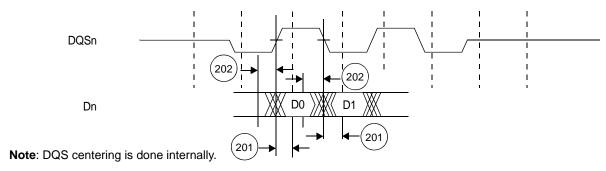


Figure 5. DDR DRAM Input Timing Diagram

#### 2.5.4.2 **DDR DRAM Output AC Timing Specifications**

Table 18 and Table 19 list the output AC timing specifications and measurement conditions for the DDR DRAM interface.

**Table 18. DDR DRAM Output AC Timing** 

No.	Parameter	Symbol	Min	Max	Unit
200	CK cycle time, (CK/CK crossing) <sup>1</sup> • 100 MHz (DDR200) • 150 MHz (DDR300)	t <sub>CK</sub>	10 6.67	_ _	ns ns
204	An/RAS/CAS/WE/CKE output setup with respect to CK	t <sub>DDKHAS</sub>	0.5 × t <sub>CK</sub> – 1000	_	ps
205	An/RAS/CAS/WE/CKE output hold with respect to CK	t <sub>DDKHAX</sub>	0.5 × t <sub>CK</sub> – 1000	_	ps
206	CSn output setup with respect to CK	t <sub>DDKHCS</sub>	0.5 × t <sub>CK</sub> – 1000	_	ps
207	CSn output hold with respect to CK	t <sub>DDKHCX</sub>	0.5 × t <sub>CK</sub> – 1000	_	ps
208	CK to DQSn <sup>2</sup>	t <sub>DDKHMH</sub>	-600	600	ps

Table 18. DDR DRAM Output AC Timing (continued)
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No.	Parameter	Symbol	Min	Max	Unit
209	Dn/DQMn output setup with respect to DQSn <sup>3</sup>	t <sub>DDKHDS,</sub> t <sub>DDKLDS</sub>	0.25 × t <sub>CK</sub> – 750	_	ps
210	Dn/DQMn output hold with respect to DQSn <sup>3</sup>	t <sub>DDKHDX</sub> , t <sub>DDKLDX</sub>	0.25 × t <sub>CK</sub> – 750	_	ps
211	DQSn preamble start <sup>4</sup>	t <sub>DDKHMP</sub>	$-0.25 \times t_{CK}$	_	ps
212	DQSn epilogue end <sup>5</sup>	t <sub>DDKHME</sub>	-600	600	ps

Notes:

- 1. All CK/CK referenced measurements are made from the crossing of the two signals ±0.1 V.
- 2. t<sub>DDKHMH</sub> can be modified through the TCFG2[WRDD] DQSS override bits. The DRAM requires that the first write data strobe arrives 75–125% of a DRAM cycle after the write command is issued. Any skew between DQSn and CK must be considered when trying to achieve this 75%–125% goal. The TCFG2[WRDD] bits can be used to shift DQSn by 1/4 DRAM cycle increments. The skew in this case refers to an internal skew existing at the signal connections. By default, the CK/CK crossing occurs in the middle of the control signal (An/RAS/CAS/WE/CKE) tenure. Setting TCFG2[ACSM] bit shifts the control signal assertion 1/2 DRAM cycle earlier than the default timing. This means that the signal is asserted no earlier than 600 ps before the CK/CK crossing and no later than 600 ps after the crossing time; the device uses 1200 ps of the skew budget (the interval from –600 to +600 ps). Timing is verified by referencing the falling edge of CK. See Chapter 10 of the MSC711x Reference Manual for details.
- 3. Determined by maximum possible skew between a data strobe (DQS) and any corresponding bit of data. The data strobe should be centered inside of the data eye.
- 4. Please note that this spec is in reference to the DQSn first rising edge. It could also be referenced from CK(r), but due to programmable delay of the write strobes (TCFG2[WRDD]), there pre-amble may be extended for a full DRAM cycle. For this reason, we reference from DQSn.
- 5. All outputs are referenced to the rising edge of CK. Note that this is essentially the CK/DQSn skew in spec 208. In addition there is no real "maximum" time for the epilogue end. JEDEC does not require this is as a device limitation, but simply for the chip to guarantee fast enough write-to-read turn-around times. This is already guaranteed by the memory controller operation.

Figure 6 shows the DDR DRAM output timing diagram.

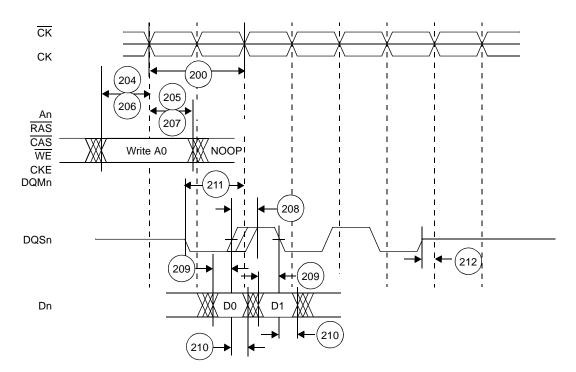


Figure 6. DDR DRAM Output Timing Diagram

#### **Electrical Characteristics**

Figure 7 provides the AC test load for the DDR DRAM bus.

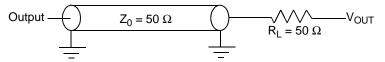


Figure 7. DDR DRAM AC Test Load

**Table 19. DDR DRAM Measurement Conditions** 

		Symbol	DDR DRAM	Unit
V <sub>TH</sub> <sup>1</sup>			V <sub>REF</sub> ± 0.31 V	V
V <sub>OUT</sub> <sup>2</sup>			$0.5 \times V_{DDM}$	V
Notes:	1. 2.	Data input threshold measurement point. Data output measurement point.		

## 2.5.5 TDM Timing

**Table 20. TDM Timing** 

No.	Characteristic	Expression	Min	Max	Units
300	TDMxRCK/TDMxTCK	TC	20.0	_	ns
301	TDMxRCK/TDMxTCK High Pulse Width	0.4 × TC	8.0	_	ns
302	TDMxRCK/TDMxTCK Low Pulse Width	0.4 × TC	8.0	_	ns
303	TDM all input Setup time		3.0	_	ns
304	TDMxRD Hold time		3.5	_	ns
305	TDMxTFS/TDMxRFS input Hold time		2.0	_	ns
306	TDMxTCK High to TDMxTD output active		4.0	_	ns
307	TDMxTCK High to TDMxTD output valid		_	14.0	ns
308	TDMxTD hold time		2.0	_	ns
309	TDMxTCK High to TDMxTD output high impedance		_	10.0	ns
310	TDMxTFS/TDMxRFS output valid		_	13.5	ns
311	TDMxTFS/TDMxRFS output hold time		2.5	_	ns

Notes: 1. Output values are based on 30 pF capacitive load.

<sup>2.</sup> Inputs are referenced to the sampling that the TDM is programmed to use. Outputs are referenced to the programming edge they are programmed to use. Use of the rising edge or falling edge as a reference is programmable. Refer to the MSC711x Reference Manual for details. TDMxTCK and TDMxRCK are shown using the rising edge.

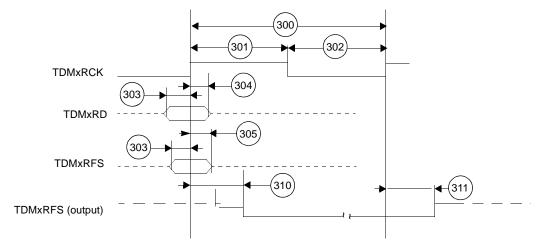


Figure 8. TDM Receive Signals

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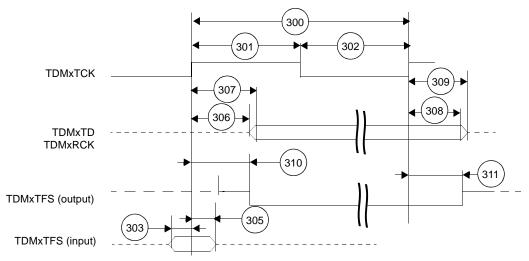


Figure 9. TDM Transmit Signals

# 2.5.6 Ethernet Timing

## 2.5.6.1 Receive Signal Timing

**Table 21. Receive Signal Timing** 

No.	Characteristics	Min	Max	Unit
800	Receive clock period:			
	MII: RXCLK (max frequency = 25 MHz)	40	_	ns
	• RMII: REFCLK (max frequency = 50 MHz)	20	_	ns
801	Receive clock pulse width high—as a percent of clock period	35	65	%
	• MII: RXCLK	14	_	ns
	• RMII: REFCLK	7	_	ns
802	Receive clock pulse width low—as a percent of clock period:	35	65	%
	• MII: RXCLK	14	_	ns
	• RMII: REFCLK	7	_	ns
803	RXDn, RX_DV, CRS_DV, RX_ER to receive clock rising edge setup time	4	_	ns
804	Receive clock rising edge to RXDn, RX_DV, CRS_DV, RX_ER hold time	2	_	ns

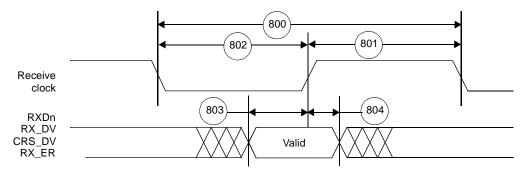


Figure 10. Ethernet Receive Signal Timing

# 2.5.6.2 Transmit Signal Timing

**Table 22. Transmit Signal Timing** 

No.	Characteristics	Min	Max	Unit
800	Transmit clock period:			
	• MII: TXCLK	40	_	ns
	• RMII: REFCLK	20	_	ns
801	Transmit clock pulse width high—as a percent of clock period	35	65	%
	• MII: RXCLK	14	_	ns
	• RMII: REFCLK	7	_	ns
802	Transmit clock pulse width low—as a percent of clock period:	35	65	%
	• MII: RXCLK	14	_	ns
	• RMII: REFCLK	7	_	ns
805	Transmit clock to TXDn, TX_EN, TX_ER invalid	4	_	ns
806	Transmit clock to TXDn, TX_EN, TX_ER valid		14	ns

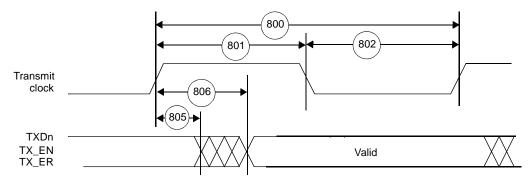


Figure 11. Ethernet Receive Signal Timing

# 2.5.6.3 Asynchronous Input Signal Timing

**Table 23. Asynchronous Input Signal Timing** 

No.	Characteristics	Min	Max	Unit
807	MII: CRS and COL minimum pulse width (1.5 × TXCLK period)     RMII: CRS_DV minimum pulse width (1.5 x REFCLK period)	60 30	_	ns ns



Figure 12. Asynchronous Input Signal Timing

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30 Freescale Semiconductor

# 2.5.6.4 Management Interface Timing

**Table 24. Ethernet Controller Management Interface Timing** 

No.	Characteristics	Min	Max	Unit
808	MDC period	400	_	ns
809	MDC pulse width high	160	_	ns
810	MDC pulse width low	160	_	ns
811	MDS falling edge to MDIO output invalid (minimum propagation delay)	0	_	ns
812	MDS falling edge to MDIO output valid (maximum propagation delay)	_	15	ns
813	MDIO input to MDC rising edge setup time	10	_	ns
814	MDC rising edge to MDIO input hold time	10	_	ns

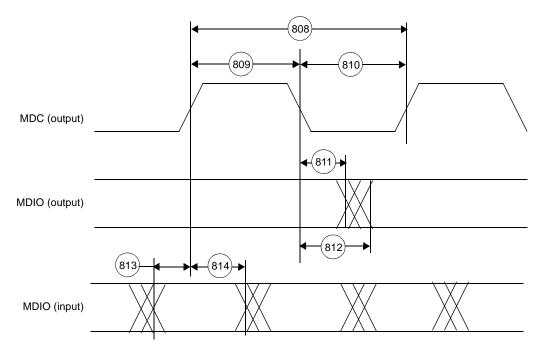


Figure 13. Serial Management Channel Timing

#### 2.5.7 HDI16 Signals

Table 25. Host Interface (HDI16) Timing<sup>1, 2</sup>

No.	Characteristics <sup>3</sup>	Expression	Value	Unit
40	Host Interface Clock period	T <sub>CORE</sub>	Note 1	ns
44a	Read data strobe minimum assertion width <sup>4</sup>	2.0 × T <sub>CORE</sub> + 9.0	Note 11	ns
	HACK read minimum assertion width			
44b	Read data strobe minimum deassertion width <sup>4</sup>	$1.5 \times T_{CORE}$	Note 11	ns
	HACK read minimum deassertion width			
44c	Read data strobe minimum deassertion width <sup>4</sup> after "Last Data Register"	$2.5 \times T_{CORE}$	Note 11	ns
	reads <sup>5,6</sup> , or between two consecutive CVR, ICR, or ISR reads <sup>7</sup> HACK minimum deassertion width after "Last Data Register" reads <sup>5,6</sup>			
45	Write data strobe minimum assertion width <sup>8</sup>	4.5 v.T	Note 11	
45	HACK write minimum assertion width	1.5 × T <sub>CORE</sub>	Note 11	ns
46	Write data strobe minimum deassertion width <sup>8</sup>			
46	HACK write minimum deassertion width after ICR, CVR and Data Register			
	writes <sup>5</sup>	$2.5 \times T_{CORE}$	Note 11	ns
47	Host data input minimum setup time before write data strobe deassertion <sup>8</sup>	2.0 % CORE		1
7,	Host data input minimum setup time before HACK write deassertion	_	2.5	ns
48	Host data input minimum hold time after write data strobe deassertion <sup>8</sup>			
	Host data input minimum hold time after HACK write deassertion	_	2.5	ns
49	Read data strobe minimum assertion to output data active from high			
	impedance <sup>4</sup>			
	HACK read minimum assertion to output data active from high impedance	_	1.0	ns
50	Read data strobe maximum assertion to output data valid <sup>4</sup>			
	HACK read maximum assertion to output data valid	$(2.0 \times T_{CORE}) + 8.0$	Note 11	ns
51	Read data strobe maximum deassertion to output data high impedance <sup>4</sup>			
	HACK read maximum deassertion to output data high impedance	_	9.0	ns
52	Output data minimum hold time after read data strobe deassertion <sup>4</sup>			
	Output data minimum hold time after HACK read deassertion	_	1.0	ns
53	HCS[1–2] minimum assertion to read data strobe assertion <sup>4</sup>	_	0.5	ns
54	HCS[1–2] minimum assertion to write data strobe assertion <sup>8</sup>	_	0.0	ns
55	HCS[1–2] maximum assertion to output data valid	$(2.0 \times T_{CORE}) + 6.0$	Note 11	ns
56	HCS[1-2] minimum hold time after data strobe deassertion <sup>9</sup>	_	0.5	ns
57	HA[0–2], HRW minimum setup time before data strobe assertion <sup>9</sup>	_	5.0	ns
58	HA[0–2], HRW minimum hold time after data strobe deassertion <sup>9</sup>	_	5.0	ns
61	Maximum delay from read data strobe deassertion to host request	$(3.0 \times T_{CORE}) + 6.0$	Note 11	ns
	deassertion for "Last Data Register" read <sup>4, 5, 10</sup>			
62	Maximum delay from write data strobe deassertion to host request			
	deassertion for "Last Data Register" write <sup>5,8,10</sup>	$(3.0 \times T_{CORE}) + 6.0$	Note 11	ns
63	Minimum delay from DMA HACK (OAD=0) or Read/Write data			
	strobe(OAD=1) deassertion to HREQ assertion.	$(2.0 \times T_{CORE}) + 1.0$	Note 11	ns
64	Maximum delay from DMA HACK (OAD=0) or Read/Write data	<b></b>		
	strobe(OAD=1) assertion to HREQ deassertion	$(5.0 \times T_{CORE}) + 6.0$	Note 11	ns

Notes:

- 1.  $T_{CORE}$  = core clock period. At 300 MHz,  $T_{CORE}$  = 3.333 ns.
- 2. In the timing diagrams below, the controls pins are drawn as active low. The pin polarity is programmable.
- 3.  $V_{DD} = 3.3 \text{ V} \pm 0.15 \text{ V}$ ;  $T_{J} = -40 ^{\circ}\text{C}$  to +105  $^{\circ}\text{C}$ ,  $C_{L} = 30 \text{ pF}$  for maximum delay timings and  $C_{L} = 0 \text{ pF}$  for minimum delay timings.
- 4. The read data strobe is HRD/HRD in the dual data strobe mode and HDS/HDS in the single data strobe mode.
- 5. For 64-bit transfers, the "last data register" is the register at address 0x7, which is the last location to be read or written in data transfers. This is RX0/TX0 in the little endian mode (HBE = 0), or RX3/TX3 in the big endian mode (HBE = 1).
- 6. This timing is applicable only if a read from the "last data register" is followed by a read from the RX[0–3] registers without first polling RXDF or HREQ bits, or waiting for the assertion of the HREQ/HREQ signal.
- $\textbf{7.} \quad \text{This timing is applicable only if two consecutive reads from one of these registers are executed.}$
- 8. The write data strobe is HWR in the dual data strobe mode and HDS in the single data strobe mode.
- 9. The data strobe is host read (HRD/HRD) or host write (HWR/HWR) in the dual data strobe mode and host data strobe (HDS/HDS) in the single data strobe mode.
- 10. The host request is HREQ/HREQ in the single host request mode and HRRQ/HRRQ and HTRQ/HTRQ in the double host request mode. HRRQ/HRRQ is deasserted only when HOTX fifo is empty, HTRQ/HTRQ is deasserted only if HORX fifo is full
- 11. Compute the value using the expression.
- 12. The read and write data strobe minimum deassertion width for non-"last data register" accesses in single and dual data strobe modes is based on timings 57 and 58.

Figure 14 and Figure 15 show HDI16 read signal timing. Figure 16 and Figure 17 show HDI16 write signal timing.

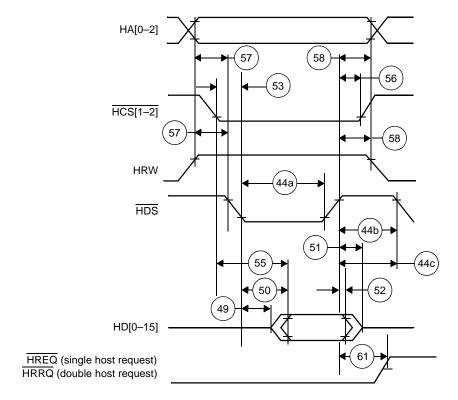


Figure 14. Read Timing Diagram, Single Data Strobe

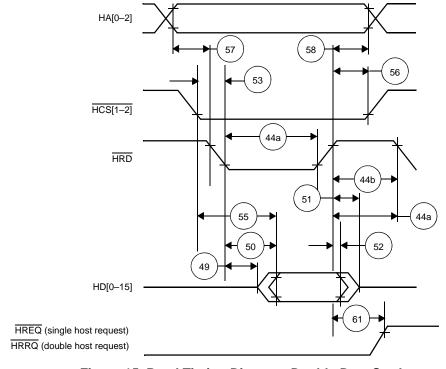


Figure 15. Read Timing Diagram, Double Data Strobe

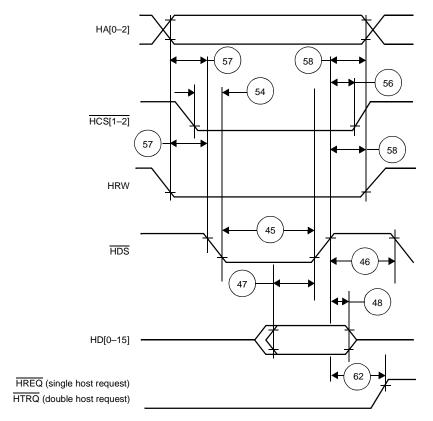


Figure 16. Write Timing Diagram, Single Data Strobe

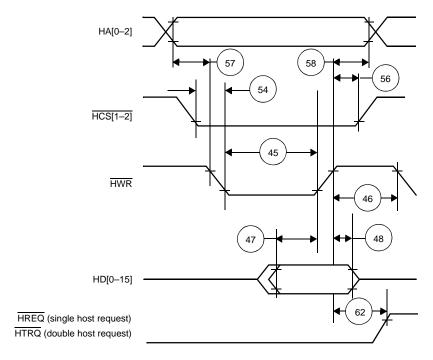


Figure 17. Write Timing Diagram, Double Data Strobe

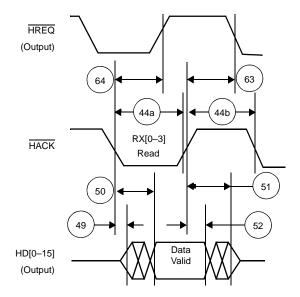


Figure 18. Host DMA Read Timing Diagram, HPCR[OAD] = 0

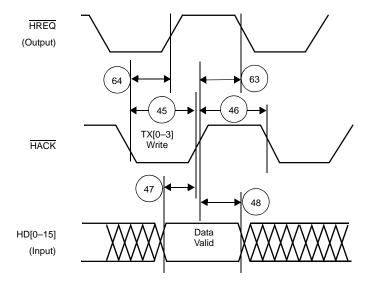


Figure 19. Host DMA Write Timing Diagram, HPCR[OAD] = 0

#### I<sup>2</sup>C Timing 2.5.8

Table 26. I<sup>2</sup>C Timing

No.	Characteristic	Fast	l lmit	
		Min	Max	Unit
450	SCL clock frequency	0	400	kHz
451	Hold time START condition	(SCL clock period/2) – 0.3	_	μs
452	SCL low period	(SCL clock period/2) – 0.3	_	μs
453	SCL high period	(SCL clock period/2) – 0.1	_	μs
454	Repeated START set-up time (not shown in figure)	2 × 1/F <sub>BCK</sub>	_	μs
455	Data hold time	0	_	μs
456	Data set-up time	250	_	ns
457	SDA and SCL rise time	_	700	ns
458	SDA and SCL fall time	_	300	ns
459	Set-up time for STOP	(SCL clock period/2) – 0.7	_	μs
460	Bus free time between STOP and START	(SCL clock period/2) – 0.3	_	μs
Note:	SDA set-up time is referenced to the rising edge of SCL. SDA hold time is referenced to the falling edge of SCL. Load capacitance on SDA and SCL is 400 pF.			

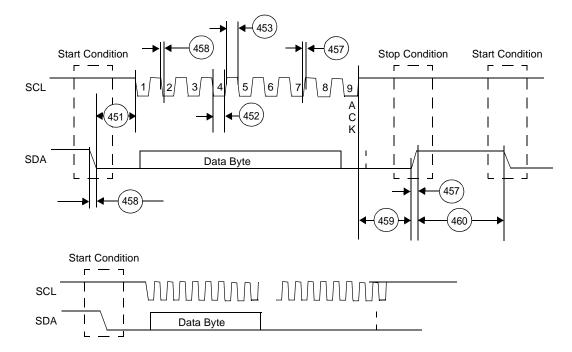


Figure 20. I<sup>2</sup>C Timing Diagram

# 2.5.9 UART Timing

**Table 27. UART Timing** 

No.	Characteristics	Expression	Min	Max	Unit
_	Internal bus clock (APBCLK)	F <sub>CORE</sub> /2	_	133	MHz
_	Internal bus clock period (1/APBCLK)	T <sub>APBCLK</sub>	7.52	_	ns
400	URXD and UTXD inputs high/low duration	16×T <sub>APBCLK</sub>	120.3	_	ns
401	URXD and UTXD inputs rise/fall time		_	5	ns
402	UTXD output rise/fall time		_	5	ns

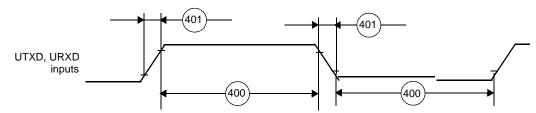


Figure 21. UART Input Timing

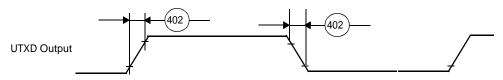


Figure 22. UART Output Timing

# **2.5.10 EE Timing**

Table 28. EE0 Timing

Number Characteristics		Туре	Min	
65	EE0 input to the core	Asynchronous	4 core clock periods	
66 EE0 output from the core		Synchronous to core clock	1 core clock period	
Notes: 1. The core clock is the SC1400 core clock. The ratio between the core clock and CLKOUT is configured during power-on-reset.				

- 2. Configure the direction of the EE pin in the EE\_CTRL register (see the SC140/SC1400 Core Reference Manual for details.
- 3. Refer to **Table 1-11** on page 1-16 for details on EE pin functionality.

Figure 24 shows the signal behavior of the EE pin.

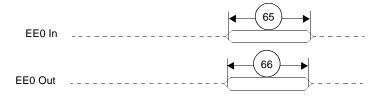


Figure 23. EE Pin Timing

## 2.5.11 Event Timing

**Table 29. EVNT Signal Timing** 

Number		Characteristics	Туре	Min
67 EVNT as input		EVNT as input	Asynchronous	1.5 × APBCLK periods
68 EVNT as output		EVNT as output	Synchronous to core clock	1 APBCLK period
Notes: 1. Refer to Table 27 for a definition of the APBCLK period. 2. Direction of the EVNT signal is configured through the GPIO and Event port registers. 3. Refer to the signal chapter in the MSC711x Reference Manual for details on EVNT pin functionality.				

Figure 24 shows the signal behavior of the EVNT pins.

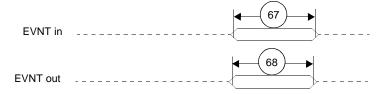


Figure 24. EVNT Pin Timing

## 2.5.12 GPIO Timing

Table 30. GPIO Signal Timing 1,2,3

Number	Characteristics	Characteristics Type	
601	GPI <sup>4.5</sup>	Asynchronous	1.5 × APBCLK periods
602	GPO <sup>5</sup>	Synchronous to core clock	1 APBCLK period
603	Port A edge-sensitive interrupt	Asynchronous	1.5 × APBCLK periods
604	Port A level-sensitive interrupt	Asynchronous	3 × APBCLK periods <sup>6</sup>

Notes: 1. Refer to Table 27 for a definition of the APBCLK period.

- 2. Direction of the GPIO signal is configured through the GPIO port registers.
- 3. Refer to **Section 1.5** for details on GPIO pin functionality.
- 4. GPI data is synchronized to the APBCLK internally and the minimum listed is the capability of the hardware to capture data into a register when the GPADR is read. The specification is not tested due to the asynchronous nature of the input and dependence on the state of the DSP core. It is guaranteed by design.
- 5. The output signals cannot toggle faster than 75 MHz.
- Level-sensitive interrupts should be held low until the system determines (via the service routine) that the interrupt is acknowledged.

Figure 25 shows the signal behavior of the GPI/GPO pins.

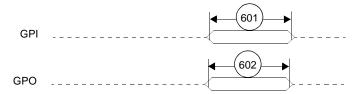


Figure 25. GPI/GPO Pin Timing

# 2.5.13 JTAG Signals

**Table 31. JTAG Timing** 

No.	Characteristics	All freq	luencies	Unit		
NO.	Characteristics	Min	Max			
700	TCK frequency of operation (1/( $T_C \times 3$ )  Note: $T_C = 1/CLOCK$ which is the period of the core clock. The TCK frequency must less than 1/3 of the core frequency with an absolute maximum limit of 40 MHz.	0.0	40.0	MHz		
701	TCK cycle time	25.0	_	ns		
702	TCK clock pulse width measured at V <sub>M =</sub> 1.6 V	11.0	_	ns		
703	TCK rise and fall times	0.0	3.0	ns		
704	Boundary scan input data set-up time	5.0	_	ns		
705	Boundary scan input data hold time	14.0	_	ns		
706	TCK low to output data valid	0.0	20.0	ns		
707	TCK low to output high impedance	0.0	20.0	ns		
708	TMS, TDI data set-up time	5.0	_	ns		
709	TMS, TDI data hold time	14.0	_	ns		
710	TCK low to TDO data valid	0.0	24.0	ns		
711	TCK low to TDO high impedance	0.0	10.0	ns		
712	TRST assert time 100.0 — n					
Note:	All timings apply to OCE module data transfers as the OCE module uses the JTAG port as an interface.					

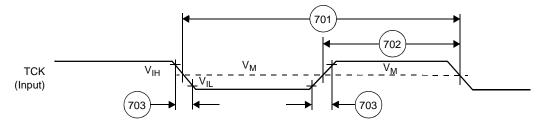


Figure 26. Test Clock Input Timing Diagram

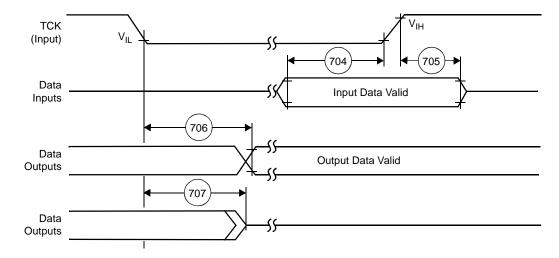


Figure 27. Boundary Scan (JTAG) Timing Diagram

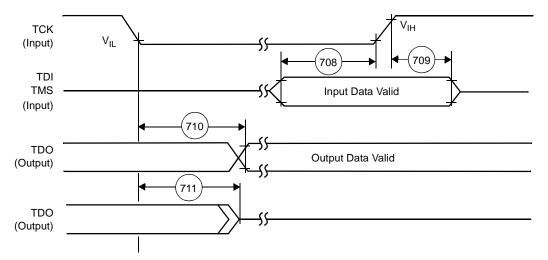


Figure 28. Test Access Port Timing Diagram



Figure 29. TRST Timing Diagram

# 3 Hardware Design Considerations

This section described various areas to consider when incorporating the MSC7116 device into a system design.

## 3.1 Thermal Design Considerations

An estimation of the chip-junction temperature, T<sub>I</sub>, in °C can be obtained from the following:

$$T_J = T_A + (R_{\Theta JA} \times P_D)$$
 Eqn. 1

where

 $T_A$  = ambient temperature near the package (°C)

 $R_{AIA}$  = junction-to-ambient thermal resistance (°C/W)

 $P_D = P_{INT} + P_{I/O} = power dissipation in the package (W)$ 

 $P_{INT} = I_{DD} \times V_{DD} = internal power dissipation (W)$ 

 $P_{I/O}$  = power dissipated from device on output pins (W)

The power dissipation values for the MSC7116 are listed in **Table 4**. The ambient temperature for the device is the air temperature in the immediate vicinity that would cool the device. The junction-to-ambient thermal resistances are JEDEC standard values that provide a quick and easy estimation of thermal performance. There are two values in common usage: the value determined on a single layer board and the value obtained on a board with two planes. The value that more closely approximates a specific application depends on the power dissipated by other components on the printed circuit board (PCB). The value obtained using a single layer board is appropriate for tightly packed PCB configurations. The value obtained using a board with internal planes is more appropriate for boards with low power dissipation (less than 0.02 W/cm² with natural convection) and well separated components. Based on an estimation of junction temperature using this technique, determine whether a more detailed thermal analysis is required. Standard thermal management techniques can be used to maintain the device thermal junction temperature below its maximum. If T<sub>J</sub> appears to be too high, either lower the ambient temperature or the power dissipation of the chip.

You can verify the junction temperature by measuring the case temperature using a small diameter thermocouple (40 gauge is recommended) or an infrared temperature sensor on a spot on the device case. Use the following equation to determine T<sub>I</sub>:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$
 Eqn. 2

where

 $T_T$  = thermocouple (or infrared) temperature on top of the package (°C)

 $\Psi_{JT}$  = thermal characterization parameter (°C/W)

 $P_D$  = power dissipation in the package (W)

## 3.2 Power Supply Design Considerations

This section outlines the MSC7116 power considerations: power supply, power sequencing, power planes, decoupling, power supply filtering, and power consumption. It also presents a recommended power supply design and options for low-power consumption. For information on AC/DC electrical specifications and thermal characteristics, refer to **Section 2**.

## 3.2.1 Power Supply

The MSC7116 requires four input voltages, as shown in **Table 32**.

Table 32. MSC7116 Voltages

Voltage	Symbol	Value
Core	V <sub>DDC</sub>	1.2 V
Memory	$V_{DDM}$	2.5 V
Reference	V <sub>REF</sub>	1.25 V
I/O	V <sub>DDIO</sub>	3.3 V

You should supply the MSC7116 core voltage via a variable switching supply or regulator to allow for compatibility with possible core voltage changes on future silicon revisions. The core voltage is supplied with 1.2 V (+5% and -10%) across  $V_{DDC}$  and GND and the I/O section is supplied with 3.3 V ( $\pm$  10%) across  $V_{DDIO}$  and GND. The memory and reference voltages supply the DDR memory controller block. The memory voltage is supplied with 2.5 V across  $V_{DDM}$  and GND. The reference voltage is supplied across  $V_{REF}$  and GND and must be between  $0.49 \times V_{DDM}$  and  $0.51 \times V_{DDM}$ . Refer to the JEDEC standard JESD8 (Stub Series Terminated Logic for 2.5 Volts (STTL\_2)) for memory voltage supply requirements.

#### 3.2.2 Power Sequencing

One consequence of multiple power supplies is that the voltage rails ramp up at different rates when power is initially applied. The rates depend on the power supply, the type of load on each power supply, and the way different voltages are derived. It is extremely important to observe the power up and power down sequences at the board level to avoid latch-up, forward biasing of ESD devices, and excessive currents, which all lead to severe device damage.

**Note:** There are five possible power-up/power-down sequence cases. The first four cases listed in the following sections are recommended for new designs. The fifth case is not recommended for new designs and must be carefully evaluated for current spike risks based on actual information for the specific application.

#### 3.2.2.1 Case 1

The power-up sequence is as follows:

- 1. Turn on the  $V_{DDIO}$  (3.3 V) supply first.
- 2. Turn on the  $V_{DDC}$  (1.2 V) supply second.
- 3. Turn on the  $V_{DDM}$  (2.5 V) supply third.
- 4. Turn on the  $V_{REF}$  (1.25 V) supply fourth (last).

The power-down sequence is as follows:

- 1. Turn off the  $V_{REF}$  (1.25 V) supply first.
- 2. Turn off the  $V_{DDM}$  (2.5 V) supply second.
- 3. Turn off the V<sub>DDC</sub> (1.2 V) supply third.
- 4. Turn of the V<sub>DDIO</sub> (3.3 V) supply fourth (last).

Use the following guidelines:

- Make sure that the time interval between the ramp-down of  $V_{DDIO}$  and  $V_{DDC}$  is less than 10 ms.
- Make sure that the time interval between the ramp-up or ramp-down for V<sub>DDC</sub> and V<sub>DDM</sub> is less than 10 ms for power-up and power-down.
- Refer to **Figure 30** for relative timing for power sequencing case 1.

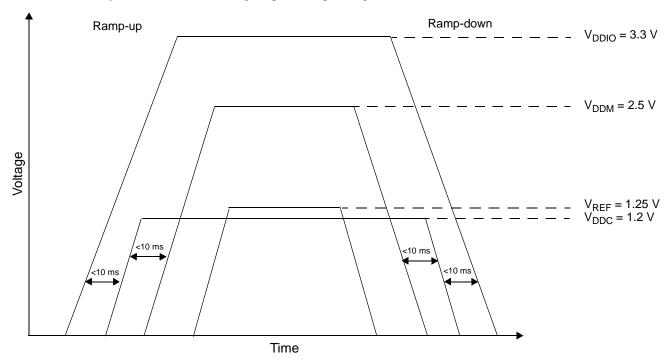


Figure 30. Voltage Sequencing Case 1

#### 3.2.2.2 Case 2

The power-up sequence is as follows:

- 1. Turn on the  $V_{DDIO}$  (3.3 V) supply first.
- 2. Turn on the  $V_{DDC}$  (1.2 V) and  $V_{DDM}$  (2.5 V) supplies simultaneously (second).
- 3. Turn on the  $V_{REF}$  (1.25 V) supply last (third).

**Note:** Make sure that the time interval between the ramp-up of  $V_{DDIO}$  and  $V_{DDC}/V_{DDM}$  is less than 10 ms.

The power-down sequence is as follows:

- 1. Turn off the  $V_{REF}$  (1.25 V) supply first.
- 2. Turn off the  $V_{DDM}$  (2.5 V) supply second.
- 3. Turn off the  $V_{DDC}$  (1.2 V) supply third.
- 4. Turn of the  $V_{DDIO}$  (3.3 V) supply fourth (last).

Use the following guidelines:

- Make sure that the time interval between the ramp-down for  $V_{DDIO}$  and  $V_{DDC}$  is less than 10 ms.
- Make sure that the time interval between the ramp-up or ramp-down for V<sub>DDC</sub> and V<sub>DDM</sub> is less than 10 ms for power-up and power-down.
- Refer to **Figure 31** for relative timing for Case 2.

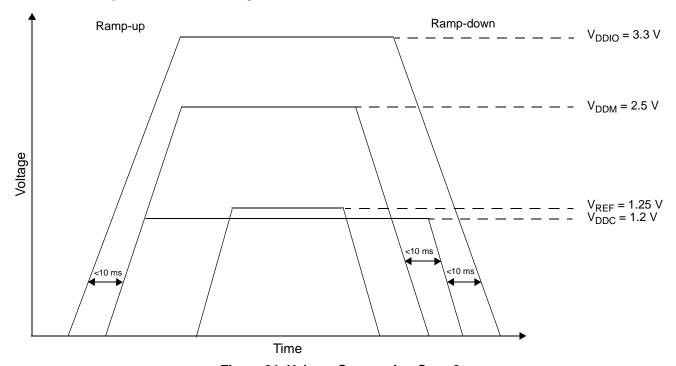


Figure 31. Voltage Sequencing Case 2

#### 3.2.2.3 Case 3

The power-up sequence is as follows:

- 1. Turn on the V<sub>DDIO</sub> (3.3 V) supply first.
- 2. Turn on the  $V_{DDC}$  (1.2 V) supply second.
- 3. Turn on the  $V_{DDM}$  (2.5 V) and  $V_{REF}$  (1.25 V) supplies simultaneously (third).

**Note:** Make sure that the time interval between the ramp-up of  $V_{DDIO}$  and  $V_{DDC}$  is less than 10 ms.

The power-down sequence is as follows:

- 1. Turn off the  $V_{DDM}$  (2.5 V) and  $V_{REF}$  (1.25 V) supplies simultaneously (first).
- 2. Turn off the  $V_{DDC}$  (1.2 V) supply second.
- 3. Turn of the  $V_{DDIO}$  (3.3 V) supply third (last).

Use the following guidelines:

- Make sure that the time interval between the ramp-down for  $V_{DDIO}$  and  $V_{DDC}$  is less than 10 ms.
- Make sure that the time interval between the ramp-up or ramp-down time for V<sub>DDC</sub> and V<sub>DDM</sub> is less than 10 ms for power-up and power-down.
- Refer to **Figure 32** for relative timing for Case 3.

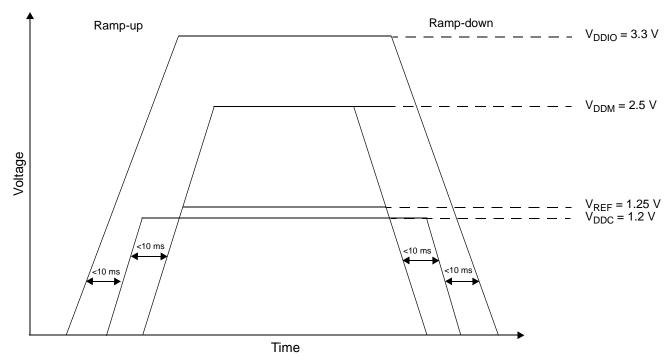


Figure 32. Voltage Sequencing Case 3

#### 3.2.2.4 Case 4

The power-up sequence is as follows:

- 1. Turn on the V<sub>DDIO</sub> (3.3 V) supply first.
- 2. Turn on the  $V_{DDC}$  (1.2 V),  $V_{DDM}$  (2.5 V), and  $V_{REF}$  (1.25 V) supplies simultaneously (second).

**Note:** Make sure that the time interval between the ramp-up of  $V_{DDIO}$  and  $V_{DDC}$  is less than 10 ms.

The power-down sequence is as follows:

- 1. Turn off the  $V_{DDC}$  (1.2 V),  $V_{REF}$  (1.25 V), and  $V_{DDM}$  (2.5 V) supplies simultaneously (first).
- 2. Turn of the  $V_{DDIO}$  (3.3 V) supply last.

Use the following guidelines:

- Make sure that the time interval between the ramp-up or ramp-down time for V<sub>DDC</sub> and V<sub>DDM</sub> is less than 10 ms for power-up and power-down.
- Refer to **Figure 33** for relative timing for Case 4.

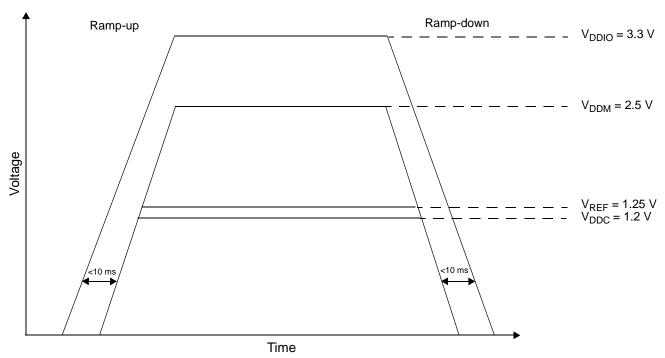


Figure 33. Voltage Sequencing Case 4

#### 3.2.2.5 Case 5 (not recommended for new designs)

The power-up sequence is as follows:

- 1. Turn on the V<sub>DDIO</sub> (3.3 V) supply first.
- 2. Turn on the  $V_{DDM}$  (2.5 V) supply second.
- 3. Turn on the  $V_{DDC}$  (1.2 V) supply third.
- 4. Turn on the  $V_{REF}$  (1.25 V) supply fourth (last).

**Note:** Make sure that the time interval between the ramp-up of  $V_{DDIO}$  and  $V_{DDM}$  is less than 10 ms.

The power-down sequence is as follows:

- 1. Turn off the  $V_{REF}$  (1.25 V) supply first.
- 2. Turn off the  $V_{DDC}$  (1.2 V) supply second.
- 3. Turn off the  $V_{DDM}$  (2.5 V) supply third.
- 4. Turn of the  $V_{DDIO}$  (3.3 V) supply fourth (last).

Use the following guidelines:

- Make sure that the time interval between the ramp-down of  $V_{DDIO}$  and  $V_{DDM}$  is less than 10 ms.
- Make sure that the time interval between the ramp-up or ramp-down for V<sub>DDC</sub> and V<sub>DDM</sub> is less than 2 ms for power-up and power-down.
- Refer to **Figure 34** for relative timing for power sequencing case 5.

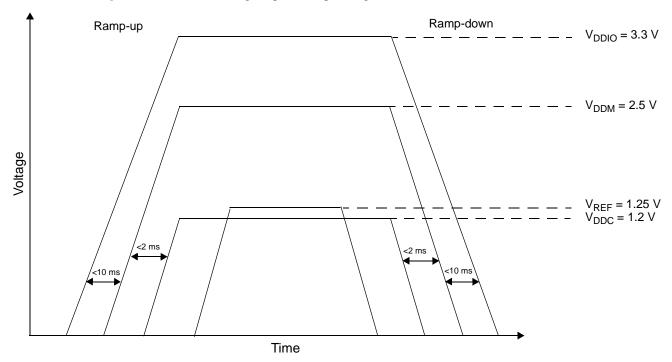


Figure 34. Voltage Sequencing Case 5

Note: Cases 1, 2, 3, and 4 are recommended for system design. Designs that use Case 5 may have large current spikes on the V<sub>DDM</sub> supply at startup and is not recommended for most designs. If a design uses case 5, it must accommodate the potential current spikes. Verify risks related to current spikes using actual information for the specific application.

#### 3.2.3 Power Planes

Each power supply pin (V<sub>DDC</sub>, V<sub>DDM</sub>, and V<sub>DDIO</sub>) should have a low-impedance path to the board power supply. Each GND pin should be provided with a low-impedance path to ground. The power supply pins drive distinct groups of logic on the device. The MSC7116 V<sub>DDC</sub> power supply pins should be bypassed to ground using decoupling capacitors. The capacitor leads and associated printed circuit traces connecting to device power pins and GND should be kept to less than half an inch per capacitor lead. A minimum four-layer board that employs two inner layers as power and GND planes is recommended. See **Section 3.5** for DDR Controller power guidelines.

### 3.2.4 Decoupling

Both the I/O voltage and core voltage should be decoupled for switching noise. For I/O decoupling, use standard capacitor values of  $0.01~\mu F$  for every two to three voltage pins. For core voltage decoupling, use two levels of decoupling. The first level should consist of a  $0.01~\mu F$  high frequency capacitor with low effective series resistance (ESR) and effective series inductance (ESL) for every two to three voltage pins. The second decoupling level should consist of two bulk/tantalum decoupling capacitors, one  $10~\mu F$  and one  $47~\mu F$ , (with low ESR and ESL) mounted as closely as possible to the MSC7116 voltage pins. Additionally, the maximum drop between the power supply and the DSP device should be 15~mV at 1~A.

### 3.2.5 PLL Power Supply Filtering

The MSC7116  $V_{DDPLL}$  power signal provides power to the clock generation PLL. To ensure stability of the internal clock, the power supplied to this pin should be filtered with capacitors that have low and high frequency filtering characteristics.  $V_{DDPLL}$  can be connected to  $V_{DDC}$  through a 2  $\Omega$  resistor.  $V_{SSPLL}$  can be tied directly to the GND plane. A circuit similar to the one shown in **Figure 35** is recommended. The PLL loop filter should be placed as closely as possible to the  $V_{DDPLL}$  pin (which are located on the outside edge of the silicon package) to minimize noise coupled from nearby circuits. The 0.01  $\mu$ F capacitor should be closest to  $V_{DDPLL}$ , followed by the 0.1  $\mu$ F capacitor, the 10  $\mu$ F capacitor, and finally the 2- $\Omega$  resistor to  $V_{DDC}$ . These traces should be kept short.

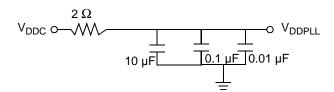


Figure 35. PLL Power Supply Filter Circuits

## 3.2.6 Power Consumption

You can reduce power consumption in your design by controlling the power consumption of the following regions of the device:

- Extended core. Use the SC1400 Stop and Wait modes by issuing a stop or wait instruction.
- Clock synthesis module. Disable the PLL, timer, watchdog, or DDR clocks or disable the CLKO pin.
- AHB subsystem. Freeze or shut down the AHB subsystem using the GPSCTL[XBR HRQ] bit.
- Peripheral subsystem. Halt the individual on-device peripherals such as the DDR memory controller, Ethernet MAC, HDI16, TDM, UART, I<sup>2</sup>C, and timer modules.

For details, see the "Clocks and Power Management" chapter of the MSC711x Reference Manual.

## 3.2.7 Power Supply Design

One of the most common ways to derive power is to use either a simple fixed or adjustable linear regulator. For the system I/O voltage supply, a simple fixed 3.3 V supply can be used. However, a separate adjustable linear regulator supply for the core voltage  $V_{DDC}$  should be implemented. For the memory power supply, regulators are available that take care of all DDR power requirements.

**Table 33. Recommended Power Supply Ratings** 

Supply	Symbol	Nominal Voltage	Current Rating
Core	V <sub>DDC</sub>	1.2 V	1.5 A per device
Memory	V <sub>DDM</sub>	2.5 V	0.5 A per device
Reference	V <sub>REF</sub>	1.25 V	10 μA per device
I/O	V <sub>DDIO</sub>	3.3 V	1.0 A per device

## 3.3 Estimated Power Usage Calculations

The following equations permit estimated power usage to be calculated for individual design conditions. Overall power is derived by totaling the power used by each of the major subsystems:

$$P_{TOTAL} = P_{CORE} + P_{PERIPHERALS} + P_{DDRIO} + P_{IO} + P_{LEAKAGE}$$
 Eqn. 3

This equation combines dynamic and static power. Dynamic power is determined using the generic equation:

$$C \times V^2 \times F \times 10^{-3} \text{ mW}$$
 Eqn. 4

where,

C = load capacitance in pF

V = peak-to-peak voltage swing in V

F = frequency in MHz

#### 3.3.1 Core Power

Estimation of core power is straightforward. It uses the generic dynamic power equation and assumes that the core load capacitance is 750 pF, core voltage swing is 1.2 V, and the core frequency is 266 MHz. This yields:

$$P_{CORF} = 750 \ pF \times (1.2 \ V)^2 \times 266 \ MHz \times 10^{-3} = 287 \ mW$$
 Eqn. 5

This equation allows for adjustments to voltage and frequency if necessary.

#### 3.3.2 Peripheral Power

Peripherals include the DDR memory controller, Ethernet controller, DMA controller, HDI16, TDM, UART, timers, GPIOs, and the I<sup>2</sup>C module. Basic power consumption by each module is assumed to be the same and is computed by using the following equation which assumes an effective load of 20 pF, core voltage swing of 1.2 V, and a switching frequency of 133 MHz. This yields:

$$P_{PERIPHERAL} = 20 \ pF \times (1.2 \ V)^2 \times 133 \ MHz \times 10^{-3} = 3.83 \ mW \ per \ peripheral$$
 Eqn. 6

Multiply this value by the number of peripherals used in the application to compute the total peripheral power consumption.

#### 3.3.3 External Memory Power

Estimation of power consumption by the DDR memory system is complex. It varies based on overall system signal line usage, termination and load levels, and switching rates. Because the DDR memory includes terminations external to the MSC7116 device, the 2.5 V power source provides the power for the termination, which is a static value of 16 mA per signal driven high. The dynamic power is computed, however, using a differential voltage swing of  $\pm 0.200$  V, yielding a peak-to-peak swing of 0.4 V. The equations for computing the DDR power are:

$$P_{DDRIO} = P_{STATIC} + P_{DYNAMIC}$$
 Eqn. 7

$$P_{STATIC} = (unused pins \times \% driven high) \times 16 \text{ mA} \times 2.5 \text{ V}$$
 Eqn. 8

$$P_{DYNAMIC} = (pin \ activity \ value) \times 20 \ pF \times (0.4 \ V)^2 \times 266 \ MHz \times 10^{-3} \ mW$$
 Eqn. 9

pin activity value = (active data lines  $\times$  % activity  $\times$  % data switching) + (active address lines  $\times$  % activity) Eqn. 10

As an example, assume the following:

unused pins = 16 (DDR uses 16-pin mode)

% driven high = 50%

active data lines = 16

% activity = 60%

% data switching = 50%

active address lines = 3

In this example, the DDR memory power consumption is:

$$P_{DDRIO} = ((16 \times 0.5) \times 16 \times 2.5) + (((16 \times 0.6 \times 0.5) + (3 \times 0.6)) \times 20 \times (0.4)^{2} \times 266 \times 10^{-3}) = 326.3 \text{ mW}$$
 Eqn. 11

#### 3.3.4 External I/O Power

The estimation of the I/O power is similar to the computation of the peripheral power estimates. The power consumption per signal line is computed assuming a maximum load of 20 pF, a voltage swing of 3.3 V, and a switching frequency of 33 MHz, which yields:

$$P_{IO} = 20 \text{ pF} \times (3.3 \text{ V})^2 \times 33 \text{ MHz} \times 10^{-3} = 7.19 \text{ mW per I/O line}$$
 Eqn. 12

Multiply this number by the number of I/O signal lines used in the application design to compute the total I/O power.

**Note:** The signal loading depends on the board routing. For systems using a single DDR device, the load could be as low as 7 pF.

## 3.3.5 Leakage Power

The leakage power is for all power supplies combined at a specific temperature. The value is temperature dependent. The observed leakage value at room temperature is 64 mW.

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## 3.3.6 Example Total Power Consumption

Using the examples in this section and assuming four peripherals and 10 I/O lines active, a total power consumption value is estimated as the following:

$$P_{TOTAL} = 287 + (4 \times 3.83) + 326.3 + (10 \times 7.19) + 64 = 764.52 \text{ mW}$$
 Eqn. 13

#### 3.4 Reset and Boot

This section describes the recommendations for configuring the MSC7116 at reset and boot.

#### 3.4.1 Reset Circuit

 $\overline{\text{HRESET}}$  is a bidirectional signal and, if driven as an input, should be driven with an open collector or open-drain device. For an open-drain output such as  $\overline{\text{HRESET}}$ , take care when driving many buffers that implement input bus-hold circuitry. The bus-hold currents can cause enough voltage drop across the pull-up resistor to change the logic level to low. Either a smaller value of pull-up or less current loading from the bus-hold drivers overcomes this issue. To avoid exceeding the MSC7116 output current, the pull-up value should not be too small (a 1 K $\Omega$  pull-up resistor is used in the MSC711xADS reference design).

### 3.4.2 Reset Configuration Pins

**Table 34** shows the MSC7116 reset configuration signals. These signals are sampled at the deassertion (rising edge) of PORESET. For details, refer to the Reset chapter of the MSC711x Reference Manual.

Signal	Description	Settings			
BM[3-0]	Determines boot mode.	See <b>Table 35</b> for details.			
SWTE	Determines watchdog functionality.	0 Watchdog timer disabled.			
		1 Watchdog timer enabled.			
HDSP	Configures HDI16 strobe polarity.	0 Host Data strobes active low.			
		1 Host Data strobes active high.			
H8BIT	Configures HDI16 operation mode.	0 HDI16 port configured for 16-bit operation.			
		1 HDI16 port configured for 8-bit operation.			

**Table 34. Reset Configuration Signals** 

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**Table 35. Boot Mode Source Selection** 

BM[3-0]	Boot Port	Input Clock Frequency	Clock Divide	PLL	CKSEL	RNG Bit	Core Clock Frequency	Comments
HDI Boot Mo	HDI Boot Modes							
0000	HDI16	< F <sub>max</sub>	N/A	N/A	00	0	< F <sub>max</sub>	Not clocked by the PLL. Can boot as 8- or 16-bit HDI.
0101	HDI16	22.2-25 MHz	1	12	11	1	266–300 MHz	Can boot as 8- or 16-bit HDI.
0010	HDI16	25-33.3 MHz	2	32	01	1	200–266 MHz	
0111	HDI16	33-66 MHz	3	12	11	1	132-264 MHz	
0100	HDI16	44.3-50 MHz	2	12	11	1	266–300 MHz	1
SPI Boot Mo	odes - Using H	A3, HCS2, BM3, I	BM2 Pins		•			
1000	SPI (SW)	< F <sub>max</sub>	N/A	N/A	00	0	< F <sub>max</sub>	The boot program automatically
1001	SPI (SW)	15.6-25 MHz	1	17	11	0	133–212.5 MHz	determines whether EEPROM
1010	SPI (SW)	33-50 MHz	2	16	11	0	132–200 MHz	or Flash memory.
1011	SPI (SW)	44.3-75 MHz	3	18	11	0	133–225 MHz	1
SPI Boot Mo	odes - Using U	RXD, UTXD, SCL	, SDA Pins		•			
1100	SPI (SW)	< F <sub>max</sub>	N/A	N/A	00	0	< F <sub>max</sub>	Boots through different set of pins.
I <sup>2</sup> C Boot Mo	des							
0001	I <sup>2</sup> C	< 100 MHz	N/A	N/A	00	0	< 100 MHz	Not clocked by the PLL. I <sup>2</sup> C is limited to a maximum bit rate of 400 Kbps. With a clock divider of 128, this limits the maximum input clock frequency to 100 MHz.
Reserved	•							
0011	Reserved	_	_	_	_	_	_	_
0110	Reserved	_	_	_	_	_	_	_
1101	Reserved	_	_	_	_	_	_	_
1110	Reserved	_	_	_	_	_	_	_
1111	Reserved	_	_	_	_	_	_	_
Notes: 1. 2. 3.	2. The clock multiplier determines the value used in the clock module CLKCTRL[PLLMLTF] field.							

# 3.4.3 Boot

After a power-on reset, the PLL is bypassed and the device is directly clocked from the CLKIN pin. Thus, the device operates slowly during the boot process. After the boot program is loaded, it can enable the PLL and start the device operating at a higher speed. The MSC7116 can boot from an external host through the HDI16 or download a user program through the I<sup>2</sup>C port. The boot operating mode is set by configuring the BM[0–3] signals sampled at the rising edge of PORESET, as shown in **Table 35**. See the *MSC711x Reference Manual* for details of boot program operation.

#### 3.4.3.1 HDI16 Boot

If the MSC7116 device boots from an external host through the HDI16, the port is configured as follows:

- Operate in Non-DMA mode.
- Operate in polled mode on the device side.
- Operate in polled mode on the external host side.
- External host must write four 16-bit values at a time with the first word as the most significant and the fourth word as the least significant.

When booting from a power-on reset, the HDI16 is additionally configurable as follows:

- 8- or 16-bit mode as specified by the H8BIT pin.
- Data strobe as specified by the HDSP and HDDS pins.

These pins are sampled only on the deassertion of power-on reset. During a boot from a hard reset, the configuration of these pins is unaffected.

**Note:** When the HDI16 is used for booting or other purposes, bit 0 is the least significant bit and not the most significant bit as for other DSP products.

## 3.4.3.2 I<sup>2</sup>C Boot

When the MSC7116 device is configured to boot from the  $I^2C$  port, the boot program configures the GPIO pins for  $I^2C$  operation. Then the MSC7116 device initiates accesses to the  $I^2C$  module, downloading data to the MSC7116 device. The  $I^2C$  interface is configured as follows:

- PLL is disabled and bypassed so that the I<sup>2</sup>C module is clocked with the IPBus clock.
- I<sup>2</sup>C interface operates in master mode and polling is used.
- EPROM operates in slave mode.
- Clock divider is set to 128.
- Address of slave during boot is 0xA0.

The IPBus clock is internally divided to generate the bit clock, as follows:

- CLKIN must be a maximum of 100 MHz
- PLL is bypassed.
- IPBus clock = CLKIN/2 is a maximum of 50 MHz.
- I<sup>2</sup>C bit clock must be less than or equal to:
  - IPBus clock/I<sup>2</sup>C clock divider
  - 50 MHz (max)/128
  - 390.6 KHz

This satisfies the maximum clock rate requirement of 400 kbps for the  $I^2C$  interface. For details on the boot procedure, see the "Boot Program" chapter of the MSC711x Reference Manual.

#### 3.4.3.3 SPI Boot

When the MSC7116 device is configured to boot from the SPI port, the boot program configures the GPIO pins for SPI operation. Then the MSC7116 device initiates accesses to the SPI module, downloading data to the MSC7116 device. When the SPI routines run in the boot ROM, the MSC7116 is always configured as the SPI master. Booting through the SPI is supported for serial EEPROM devices and serial Flash devices. When a READ\_ID instruction is issued to the serial memory device and the device returns a value of 0x00 or 0xFF, the routines for accessing a serial EEPROM are used, at a maximum frequency of 4 Mbps. Otherwise, the routines for accessing a serial Flash are used, and they can run at faster speeds. Booting is performed through one of two sets of pins:

- Main set: BM[2–3], HA3, and HCS2, which allow use of the PLL.
- Alternate set: UTXD, URXD, SDA, and SCL, which cannot be used with the PLL.

In either configuration, an error during SPI boot is flagged on the EVNT3 pin. For details on the boot procedure, see the "Boot Program" chapter of the *MSC711x Reference Manual*.

# 3.5 DDR Memory System Guidelines

MSC7116 devices contain a memory controller that provides a glueless interface to external double data rate (DDR) SDRAM memory modules with Class 2 Series Stub Termination Logic 2.5 V (SSTL\_2). There are two termination techniques, as shown in Figure 36. Technique B is the most popular termination technique.

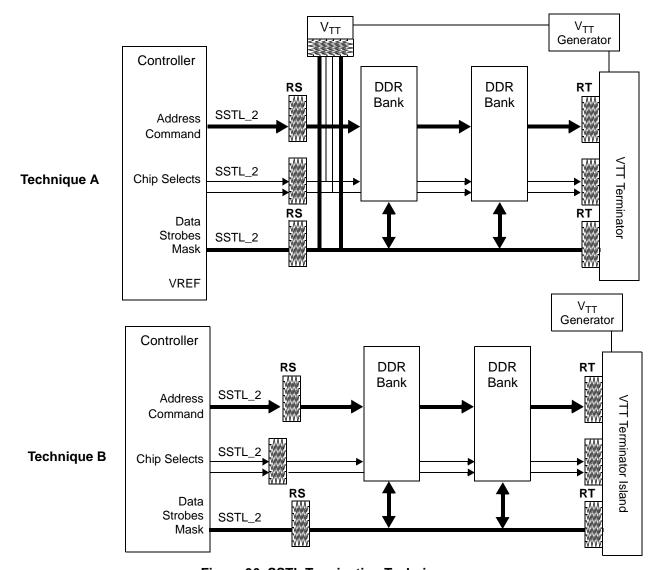


Figure 36. SSTL Termination Techniques

Figure 37 illustrates the power wattage for the resistors. Typical values for the resistors are as follows:

- $RS = 22 \Omega$
- $RT = 24 \Omega$

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Freescale Semiconductor

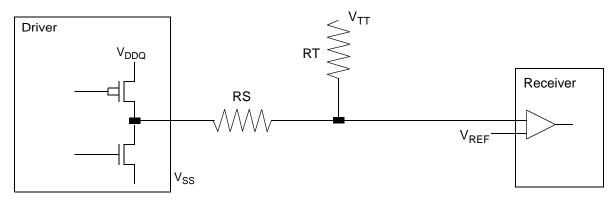


Figure 37. SSTL Power Value

## 3.5.1 V<sub>REF</sub> and V<sub>TT</sub> Design Constraints

 $V_{TT}$  and  $V_{REF}$  are isolated power supplies at the same voltage, with  $V_{TT}$  as a high current power source. This section outlines the voltage supply design needs and goals:

- Minimize the noise on both rails.
- V<sub>TT</sub> must track variation in the V<sub>REF</sub> DC offsets. Although they are isolated supplies, one possible solution is to use a single IC to generate both signals.
- Both references should have minimal drift over temperature and source supply.
- It is important to minimize the noise from coupling onto V<sub>REF</sub> as follows:
  - Isolate V<sub>REF</sub> and shield it with a ground trace.
  - Use 15–20 mm track.
  - Use 20–30 mm clearance between other traces for isolating.
  - Use the outer layer route when possible.
  - Use distributed decoupling to localize transient currents and return path and decouple with an inductance less than 3 nH.
- Max source/sink transient currents of up to 1.8 A for a 32-bit data bus.
- Use a wide island trace on the outer layer:
  - Place the island at the end of the bus.
  - Decouple both ends of the bus.
  - Use distributed decoupling across the island.
  - Place SSTL termination resistors inside the V<sub>TT</sub> island and ensure a good, solid connection.
- Place the V<sub>TT</sub> regulator as closely as possible to the termination island.
  - Reduce inductance and return path.
  - Tie current sense pin at the midpoint of the island.

## 3.5.2 Decoupling

The DDR decoupling considerations are as follows:

- DDR memory requires significantly more burst current than previous SDRAMs.
- In the worst case, up to 64 drivers may be switching states.
- Pay special attention and decouple discrete ICs per manufacturer guidelines.
- Leverage V<sub>TT</sub> island topology to minimize the number of capacitors required to supply the burst current needs of the termination rail.
- See the Micron DesignLine publication entitled *Decoupling Capacitor Calculation for a DDR Memory Channel* (http://download.micron.com/pdf/pubs/designline/3Q00dl1-4.pdf).

#### 3.5.3 General Routing

The general routing considerations for the DDR are as follows:

- All DDR signals must be routed next to a solid reference:
  - For data, next to solid ground planes.
  - For address/command, power planes if necessary.
- All DDR signals must be impedance controlled. This is system dependent, but typical values are 50–60 ohm.
- Minimize other cross-talk opportunities. As possible, maintain at least a four times the trace width spacing between all DDR signals to non-DDR signals.
- Keep the number of vias to a minimum to eliminate additional stubs and capacitance.
- Signal group routing priorities are as follows:
  - DDR clocks.
  - Route MVTT/MVREF.
  - Data group.
  - Command/address.
- Minimize data bit jitter by trace matching.

## 3.5.4 Routing Clock Distribution

The DDR clock distribution considerations are as follows:

- DDR controller supports six clock pairs:
  - 2 DIMM modules.
  - Up to 36 discrete chips.
- For route traces as for any other differential signals:
  - Maintain proper difference pair spacing.
  - Match pair traces within 25 mm.
- Match all clock traces to within 100 mm.
- Keep all clocks equally loaded in the system.
- Route clocks on inner critical layers.

## 3.5.5 Data Routing

The DDR data routing considerations are as follows:

- Route each data group (8-bits data + DQS + DM) on the same layer. Avoid switching layers within a byte group.
- Take care to match trace lengths, which is extremely important.
- To make trace matching easier, let adjacent groups be routed on alternate critical layers.
- Pin swap bits within a byte group to facilitate routing (discrete case).
- Tight trace matching is recommended within the DDR data group. Keep each 8-bit datum and its DM signal within ± 25 mm of its respective strobe.
- Minimize lengths across the entire DDR channel:
  - Between all groups maintain a delta of no more than 500 mm.
  - Allows greater flexibility in the design for readjustments as needed.
- DDR data group separation:
  - If stack-up allows, keep DDR data groups away from the address and control nets.
  - Route address and control on separate critical layers.
  - If resistor networks (RNs) are used, attempt to keep data and command lines in separate packages.

# 3.6 Connectivity Guidelines

This section summarizes the connections and special conditions, such as pull-up or pull-down resistors, for the MSC7116 device. Following are guidelines for signal groups and configuration settings:

- Clock and reset signals.
  - SWTE is used to configure the MSC7116 device and is sampled on the deassertion of PORESET, so it should be tied to V<sub>DDC</sub> or GND either directly or through pull-up or pull-down resistors until PORESET is deasserted. After PORESET, this signal can be left floating.
  - BM[0-1] configure the MSC7116 device and are sampled until PORESET is deasserted, so they should be tied to V<sub>DDIO</sub> or GND either directly or through pull-up or pull-down resistors.
  - HRESET should be pulled up.
- Interrupt signals. When used,  $\overline{IRQ}$  pins must be pulled up.
- HDI16 signals.
  - When they are configured for open-drain, the HREQ/HREQ or HTRQ/HTRQ signals require a pull-up resistor. However, these pins are also sampled at power-on reset to determine the HDI16 boot mode and may need to be pulled down. When these pins must be pulled down on reset and pulled up otherwise, a buffer can be used with the HRESET signal as the enable.
  - When the device boots through the HDI16, the HDDS, HDSP and H8BIT pins should be pulled up or down, depending on the required boot mode settings.
- Ethernet MAC/TDM2 signals. The MDIO signal requires an external pull-up resistor.
- $I^2C$  signals. The SCL and SDA signals, when programmed for  $I^2C$ , requires an external pull-up resistor.
- General-purpose I/O (GPIO) signals. An unused GPIO pin can be disconnected. After boot, program it as an output pin.
- Other signals.
  - The  $\overline{\mathsf{TEST0}}$  pin must be connected to ground.
  - The TPSEL pin should be pulled up to enable debug access via the EOnCE port and pulled down for boundary scan.
  - Pins labelled NO CONNECT (NC) must not be connected.
  - When a 16-pin double data rate (DDR) interface is used, the 16 unused data pins should be no connects (floating) if the used lines are terminated.
  - Do not connect DBREQ to DONE (as you would for the MSC8101 device). Connect DONE to one of the EVNT pins, and DBREQ to HRRQ.

# 4 Ordering Information

Consult a Freescale Semiconductor sales office or authorized distributor to determine product availability and place an order.

Part	Supply Voltage	Package Type	Pin Count	Core Frequency (MHz)	Solder Spheres	Order Number
MSC7116	1.2 V core 2.5 V memory	Molded Array Process-Ball Grid Array (MAP-BGA)	400	266	Lead-free	MSC7116VM1000
	3.3 V I/O	rulay (Wirth Borty			Lead-bearing	MSC7116VF1000

# 5 Package Information

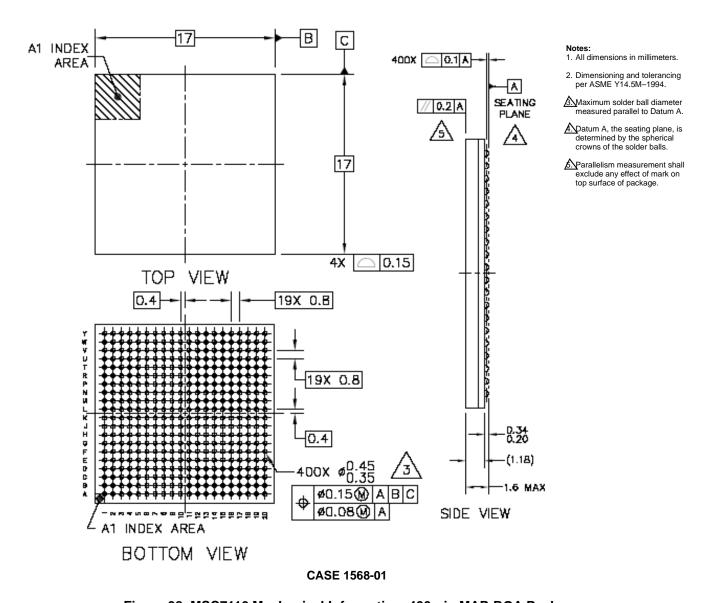


Figure 38. MSC7116 Mechanical Information, 400-pin MAP-BGA Package

# 6 Product Documentation

- *MSC711x Reference Manual* (MSC711xRM). Includes functional descriptions of the extended cores and all the internal subsystems including configuration and programming information.
- Application Notes. Cover various programming topics related to the StarCore DSP core and the MSC7116 device.
- SC140/SC1400 DSP Core Reference Manual. Covers the SC140 and SC1400 core architecture, control registers, clock registers, program control, and instruction set.

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# 7 Revision History

Table 36 provides a revision history for this data sheet.

**Table 36. Document Revision History** 

Revision	Date	Description
0	Apr 2004	Initial public release.
1	May 2004	Added ordering information and new package options.
2	Aug. 2004	<ul> <li>Updated clock parameter values.</li> <li>Updated DDR timing specifications.</li> <li>Updated I<sup>2</sup>C timing specifications.</li> </ul>
3	Sep. 2004	<ul> <li>Updated Figures 1-2 and 1-2 to correct HDSP and DBREQ.</li> <li>Corrected EE0 port reference.</li> <li>Updated ball location for HDSP.</li> </ul>
4	Jan. 2005	<ul> <li>Added signal HA3.</li> <li>Updated absolute maximum ratings, DDR DRAM capacitance specifications, clock parameters, reset timing, and TDM timing.</li> <li>Added note for timing reference for I<sup>2</sup>C interface.</li> <li>Expanded GPIO timing information.</li> <li>Corrected pin T20 and K20 signal designation.</li> <li>Corrected signal names to GPAO15 and IRQ2.</li> <li>Expanded design guidelines in Chapter 4.</li> </ul>
5	Mar. 2005	<ul> <li>Updated features list.</li> <li>Updated power specifications.</li> <li>Changed CLKIN frequency range.</li> <li>Added clock configuration information.</li> <li>Updated JTAG timings.</li> </ul>
6	Apr. 2005	Added recommended power supply ratings and updated equations to estimate power consumption.
7	Oct. 2005	Updated core and total power consumption examples.
8	Dec. 2005	Added information about the new mask set 1M88B. Affected all sections.
9	Nov. 2006	<ul> <li>Updated arrows in Host DMA Writing Timing figure.</li> <li>Updated boot overview in Section 4.4.3.</li> </ul>
10	Apr. 2007	Removed erroneous references to V <sub>CCSYN</sub> and V <sub>CCSYN1</sub> .
11	Jul. 2007	<ul> <li>Updated to new data sheet format. Reorganized and renumbered sections, figures, and tables.</li> <li>Removed all references to obsolete mask set 1L44X and corresponding specification values.</li> <li>Added a note to clarify the definition of TCK timing 700 in new Table 31.</li> <li>Reworked reset and boot sections.</li> <li>Expanded I<sup>2</sup>C boot information and added SPI boot information.</li> <li>Removed obsolete part numbers.</li> </ul>
12	Aug 2007	• The power-up and power-down sequences described in <b>Section 3.2</b> starting on page 42 have been expanded to five possible design scenarios/cases. These cases replace the previously recommended power-up/power-down sequence recommendations. <b>Section 3.2</b> has been clarified by adding subsection headings.
13	Apr 2008	• Change the PLL filter resistor from 20 $\Omega$ to 2 $\Omega$ in Section 3.2.5.

MSC7116 Data Sheet, Rev. 13

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